

High-Performance, 10 A, Dual-Phase DC-DC Converter

General Description

DA9121 is a power management unit (PMU) suitable for supplying CPUs, GPUs, DDR memory rails in single in-line pin package (SIPP) modules, smartphones, tablets, and other handheld applications.

DA9121 operates as a single-channel dual-phase buck converter, each phase requiring a small external 0.10 μ H inductor. It is capable of delivering up to 10 A output current at a 0.3 V to 1.9 V output voltage range. The 2.5 V to 5.5 V input voltage range is suitable for a wide variety of low-voltage systems, including, but not limited to, all Li-Ion battery supplied applications.

With remote sensing, the DA9121 guarantees the highest accuracy and supports multiple PCB routing scenarios without loss of performance.

The pass devices are fully integrated, so no external FETs or Schottky diodes are needed.

A programmable soft start-up can be enabled, which limits the inrush current from the input node and secures a slope-controlled rail activation.

The dynamic voltage control (DVC) supports adaptive adjustment of the supply voltage dependent on the processor load, via either a direct register write using the communication interface (I²C-compatible) or with a programmable input pin.

A configurable GPIO allows multiple I²C address selection for multiple instances of DA9121 in the same application.

DA9121 has integrated over-temperature and over-current protection for increased system reliability, without the need for external sensing components.

Key Features

- 2.5 V to 5.5 V input voltage
- 0.3 V to 1.9 V output voltage
- 4 MHz nominal switching frequency
- $\pm 1\%$ accuracy (static)
- $\pm 5\%$ accuracy (dynamic)
- I²C-compatible interface (FM+)
- Programmable GPIOs
- Programmable soft-start
- Voltage, current, and temperature supervision
- -40 °C to +85 °C ambient temperature range
- Package:
 - 24WLCSP 2.5 mm x 1.7 mm (0.4 mm pitch)
 - 24WLP 2.7 mm x 1.9 mm (0.4 mm pitch)

Applications

- SIPP modules (SoC, DRAM)
- Smartphones
- Tablet PCs
- Infotainment
- Ultrabooks™
- Wi-Fi Modules
- Game Consoles

High-Performance, 10 A, Dual-Phase DC-DC Converter

System Diagrams

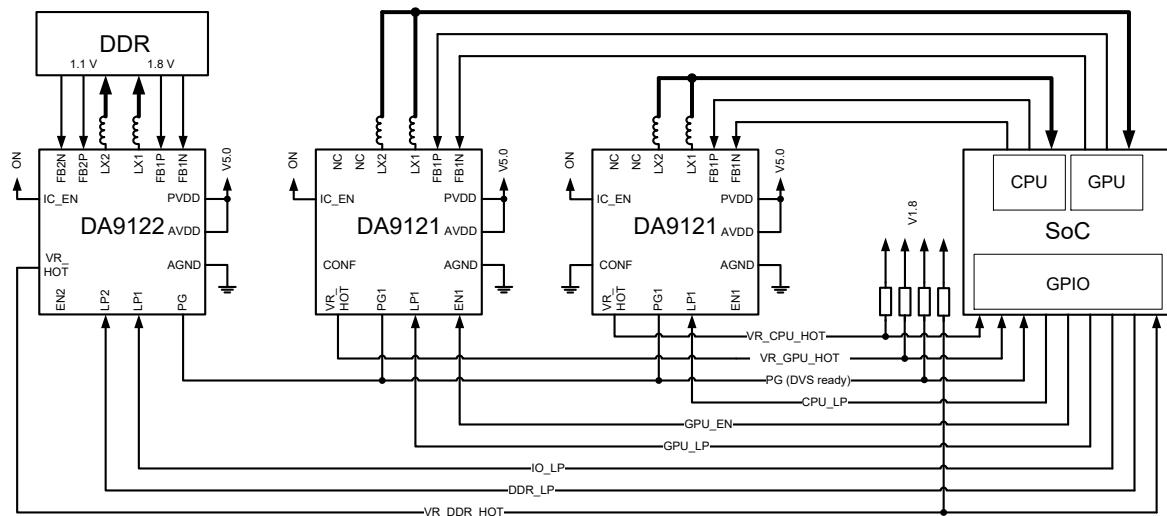


Figure 1: Typical Application Diagram (Port Control)

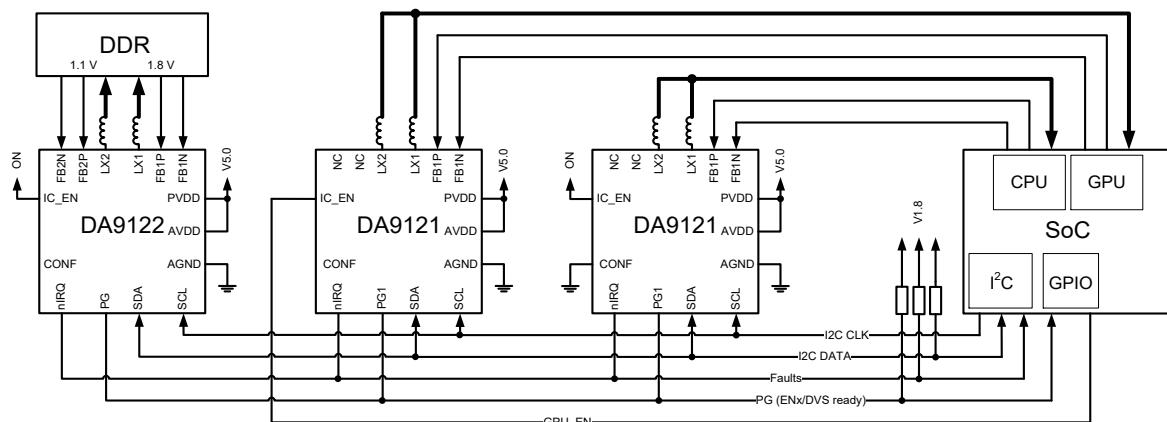


Figure 2: Typical Application Diagram (I²C Control)

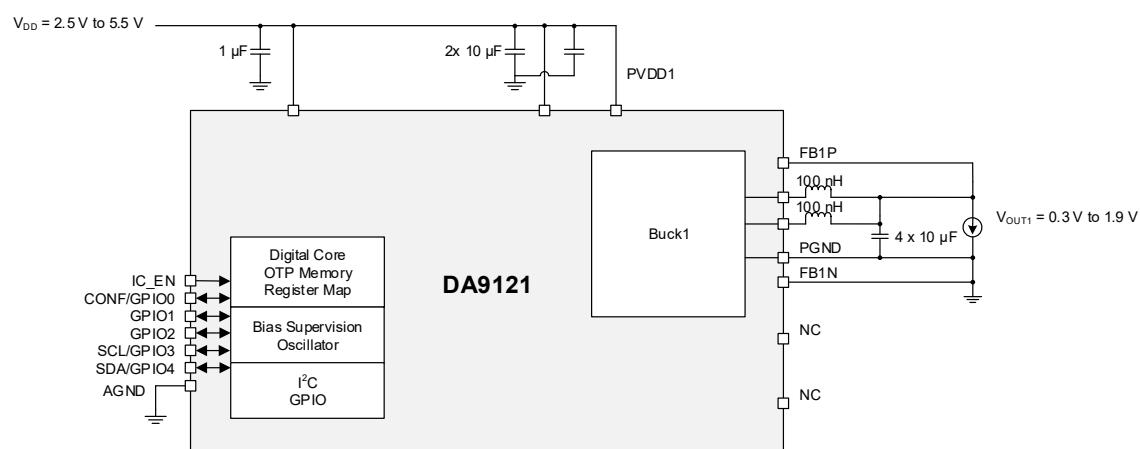


Figure 3: Simplified Schematic Diagram

High-Performance, 10 A, Dual-Phase DC-DC Converter

Contents

General Description	1
Key Features	1
Applications	1
System Diagrams	2
1 Terms and Definitions	5
2 Pinout	6
3 Characteristics	8
3.1 Absolute Maximum Ratings	8
3.2 Recommended Operating Conditions	8
3.3 Thermal Characteristics	9
3.3.1 Thermal Ratings	9
3.3.2 Power Dissipation	9
3.4 ESD Characteristics	10
3.5 Buck Characteristics	10
3.6 Performance and Supervision Characteristics	12
3.7 Digital IO Characteristics	12
3.8 Timing Characteristics	14
3.9 Typical Performance	15
4 Functional Description	19
4.1 DC-DC Buck Converter	19
4.1.1 Switching Frequency	19
4.1.2 Operation Modes and Phase Selection	19
4.1.3 Output Voltage Selection	20
4.1.4 Soft Start-Up and Shutdown	20
4.1.5 Current Limit	20
4.1.6 Thermal Protection	21
4.2 Internal Circuits	22
4.2.1 IC_EN/Chip Enable/Disable	22
4.2.2 nIRQ/Interrupt	22
4.2.3 GPIO	25
4.3 Operating Modes	27
4.3.1 ON	27
4.3.2 OFF	27
4.4 I ² C Communication	27
4.4.1 I ² C Protocol	27
5 Register Definitions	30
5.1 Register Map	30
5.1.1 System	32
5.1.2 Buck1	40
5.1.3 Serialization	44
6 Package Information	45
6.1 Package Outlines	45
6.2 Moisture Sensitivity Level	47
6.3 Package Handling	47

High-Performance, 10 A, Dual-Phase DC-DC Converter

6.4	Soldering Information	47
7	Ordering Information	48
8	Application Information	48
8.1	Capacitor Selection	48
8.2	Inductor Selection	49
9	Revision History	50

High-Performance, 10 A, Dual-Phase DC-DC Converter

1 Terms and Definitions

ATE	Automated test equipment
CPU	Central processing unit
DDR	Dual data rate
DVC	Dynamic voltage control
FET	Field effect transistor
FM+	Fast mode plus
GBD	Guaranteed by design
GBQ	Guaranteed by qualification
GBSPC	Guaranteed by statistical process characterization
GPI	General purpose input
GPIO	General purpose input/output
GPU	Graphics processing unit
IC	Integrated circuit
HW	Hardware
Li-Ion	Lithium-ion
OTP	One time programmable
PCB	Printed circuit board
PRS	Product requirements specification
SCL	Serial clock
SDA	Serial data
SIPP	Single in-line pin package
SW	Software

High-Performance, 10 A, Dual-Phase DC-DC Converter

2 Pinout

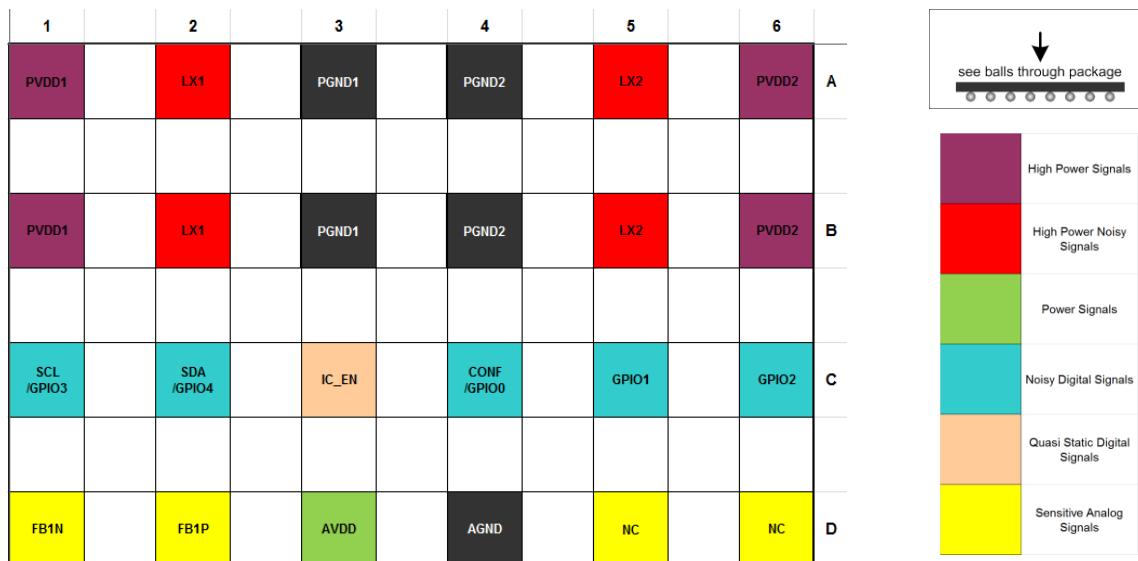


Figure 4: DA9121 Pinout Diagram (Top View)

Table 1: Pin Description

Pin No.	Pin Name	Type (Table 2)	Drive (mA)	Reset State	Description
A1, B1	PVDD1	PWR	5000		Supply voltage for buck power stage, decouple with 10 μ F and connect to same source as AVDD
A2, B2	LX1	AIO	5000		Switch node of buck, connect a 100 nH inductor between LX1 and output capacitor
A3, B3	PGND1	GND	5000		Buck power stage VSS rail
A4, B4	PGND2	GND	5000		Buck power stage VSS rail
A5, B5	LX2	AIO	5000		Switch node of buck, connect a 100 nH inductor between LX1 and output capacitor
A6, B6	PVDD2	PWR	5000		Supply voltage for buck power stage, decouple with 10 μ F and connect to same source as AVDD
C1	SCL/GPIO3	DIO	15		I ² C clock or general purpose I/O
C2	SDA/GPIO4	DIO	15		I ² C data or general purpose I/O
C3	IC_EN	AI	10		Powers up SW control interface and auxiliary circuitry (including bandgap, oscillator, and references).
C4	CONF/GPIO0	AI/DIO	10		Chip configuration or general purpose I/O
C5	GPIO1	DIO	10		General purpose I/O
C6	GPIO2	DIO	10		General purpose I/O
D1	FB1N	AI	10		Buck negative node of differential voltage feedback, connect to VSS at point of load
D2	FB1P	AI	10		Buck positive node of differential voltage feedback, connect to V _{OUT1} at point of load
D3	AVDD	PWR	10		Supply rail for analog control circuitry, decouple with 1 μ F and connect to same source as PVDD

**High-Performance, 10 A,
Dual-Phase DC-DC Converter**

Pin No.	Pin Name	Type (Table 2)	Drive (mA)	Reset State	Description
D4	AGND	GND	10		Analog control and auxiliary circuitry VSS
D5	NC	AI			Not used
D6	NC	AI			Not used

Table 2: Pin Type Definition

Pin Type	Description	Pin Type	Description
DI	Digital input	AI	Analog input
DO	Digital output	AO	Analog output
DIO	Digital input/output	AIO	Analog input/output
PWR	Power	GND	Ground

High-Performance, 10 A, Dual-Phase DC-DC Converter

3 Characteristics

3.1 Absolute Maximum Ratings

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, so functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification are not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

Table 3: Absolute Maximum Ratings

Parameter	Description	Conditions	Min	Max	Unit
T_{STG}	Storage temperature		-65	150	°C
T_J	Junction temperature		-40	150	°C
V_{SYS}	System supply voltage		-0.3	6.0	V
V_{PIN}	Voltage on pins		-0.3	6.0	V

3.2 Recommended Operating Conditions

Table 4: Recommended Operating Conditions

Parameter	Description	Conditions (Note 1)	Min	Typ	Max	Unit
V_{SYS}	System supply voltage		2.5		5.5	V
V_{PIN}	Voltage on pins		-0.3		$V_{SYS} + 0.3$	V
T_J	Junction temperature		-40		125	°C
T_A	Ambient temperature		-40		85	°C

Note 1 Within the specified limits, a lifetime of 10 years is guaranteed. If operating outside of these recommended conditions, please consult with Dialog Semiconductor.

High-Performance, 10 A, Dual-Phase DC-DC Converter

3.3 Thermal Characteristics

3.3.1 Thermal Ratings

Table 5: Package Ratings

Parameter	Description	Conditions	Min	Typ	Max	Unit
θ_{JA_WLCSP}	WLCSP Package thermal resistance Note 1			32.7		°C/W
θ_{JA_WLP}	WLP Package thermal resistance Note 1			34.8		°C/W

Note 1 Obtained from package thermal simulation, 2S2P4L board (JEDEC), influenced by PCB technology and layout.

3.3.2 Power Dissipation

Table 6: Power Dissipation

Parameter	Description	Conditions	Min	Typ	Max	Unit
P_D	Power dissipation	Derating factor above $T_A = 70^\circ\text{C}$: 30.6 mW/°C (1/ θ_{JA})		2140		mW

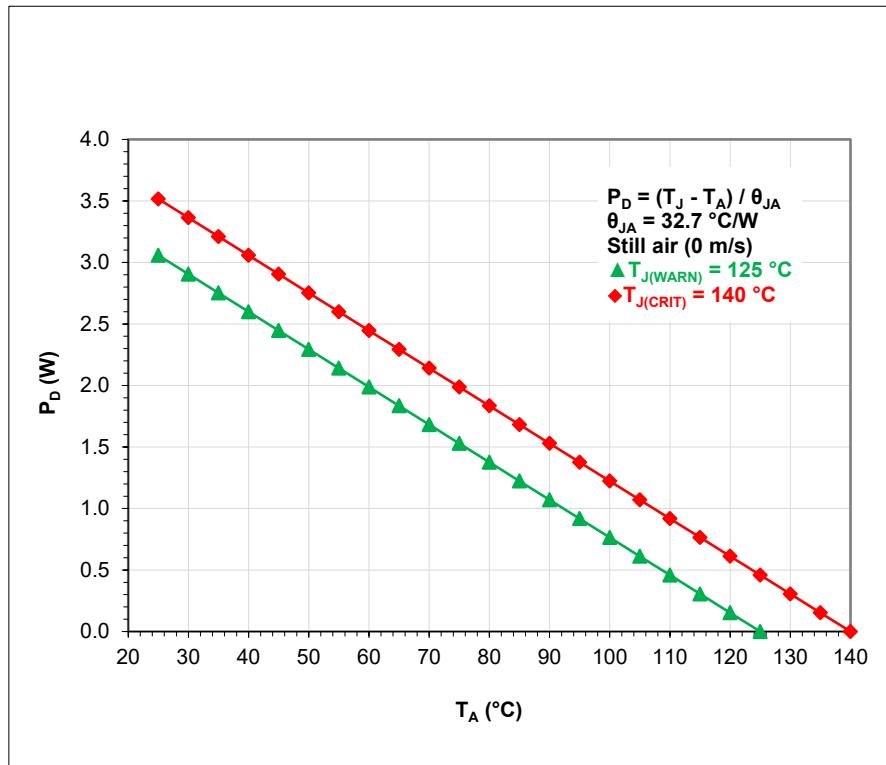


Figure 5: 24WLCSP Power Derating Curve

High-Performance, 10 A, Dual-Phase DC-DC Converter

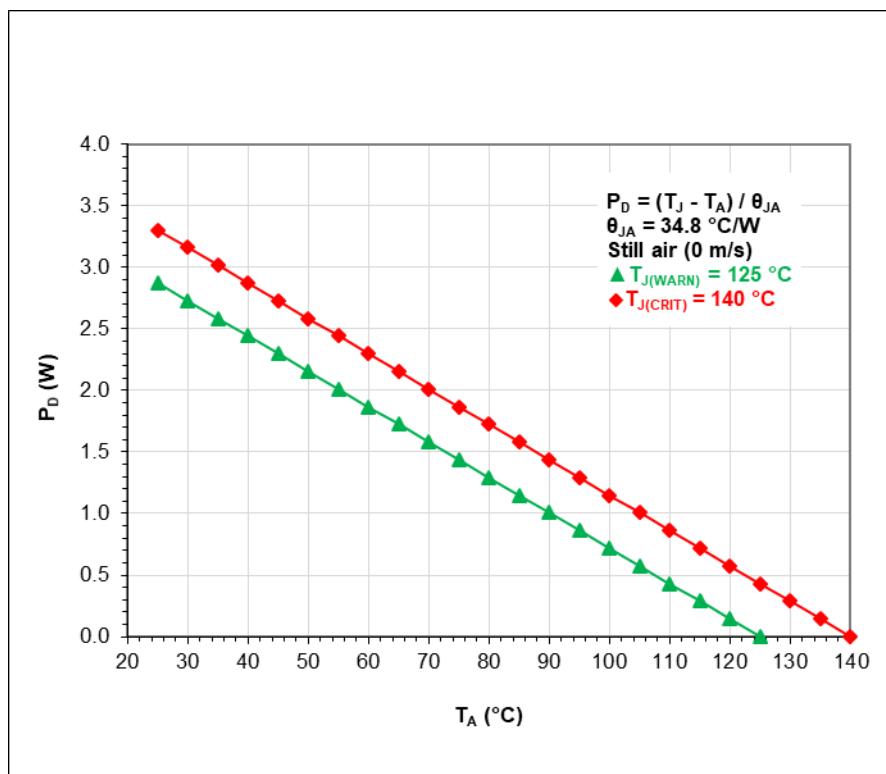


Figure 6: 24WLP Power Derating Curve

3.4 ESD Characteristics

Table 7: ESD Characteristics

Parameter	Description	Conditions	Min	Typ	Max	Unit
V _{ESD_HBM}	ESD protection, human body model (HBM)				2	kV

3.5 Buck Characteristics

Unless otherwise noted, the following is valid for T_j = -40 °C to +125 °C, V_{SYS} = 2.5 V to 5.5 V.

Table 8: Buck Electrical Characteristics

Parameter	Description	Conditions	Min	Typ	Max	Unit
External Electrical Conditions						
V _{IN}	Input voltage	V _{IN} = V _{SYS}	2.5		5.5	V
C _{OUT}	Output capacitance, per phase, including voltage and temperature coefficient		-40 %	2 x 10	+30 %	μF
ESR _{COUT}	Output capacitor series resistance, per phase	f > 100 kHz		2		mΩ
L	Inductor value, per phase, including current and temperature dependence		-50 %	0.1	+20 %	μH
DCR _L	Inductor DC resistance			30	50	mΩ

**High-Performance, 10 A,
Dual-Phase DC-DC Converter**

Parameter	Description	Conditions	Min	Typ	Max	Unit
Electrical Performance						
V _{OUT}	Output voltage, programmable in 10 mV steps	I _{OUT} = 0 mA to I _{MAX} V _{IN} = 2.5 V to 5.5 V	0.3		1.57	V
V _{OUT_LIM}	Output voltage, programmable in 10 mV steps	I _{OUT} = 0 mA to I _{MAX} V _{IN} = 3.0 V to 5.5 V	0.3		1.9	V
I _{LIM}	Current limit, programmable per phase <i>Note 1</i>	CHx_ILIM = 1010	-20 %	8	+20 %	A
V _{OUT_ACC}	Output voltage accuracy, including static line and load regulation	V _{OUT} ≥ 1 V	-1		1	%
V _{OUT_ACC}	Output voltage accuracy, including static line and load regulation	V _{OUT} < 1 V	-10		10	mV
V _{THR_PG_RISE}	Power good voltage threshold for rising	V _{OUT} = V _{BUCK}	-80	-50	-20	mV
V _{THR_PG_DWN}	Power good voltage threshold for falling	V _{OUT} = V _{BUCK}	-160	-130	-100	mV
V _{THR_HV}	High V _{OUT} voltage threshold	V _{OUT} = V _{BUCK}	100	150	200	mV
V _{OUT_TR_LINE}	Line transient response	V _{IN} = 3 V to 3.6 V I _{OUT} = 0.5 * I _{MAX} dt = 10 µs		15		mV
f _{SW}	Switching frequency, post-trim			4		MHz
t _{ON_MIN}	Minimum turn-on pulse 0 % duty is also supported			20		ns
t _{BUCK_EN}	Turn-on time	CHx_EN = high			20	µs
R _{PD}	Output pull-down resistance for each phase at the LX node, see BUCK<x>_PD_DIS	V _{IN} = 3.7 V V _{OUT} = 0.5 V	100	150	200	Ω
R _{ON_PMOS}	On resistance of switching PMOS, per phase	V _{IN} = 3.7 V		36		mΩ
R _{ON_NMOS}	On resistance of switching NMOS, per phase	V _{IN} = 3.7 V		17		mΩ
AUTO Mode						
V _{OUT_TR_LD_2_PH}	Load transient response, phase shedding enabled	V _{OUT} = 1 V I _{OUT} = 0 A to 10 A dI/dt = 10 A/µs		±5		%

High-Performance, 10 A, Dual-Phase DC-DC Converter

Parameter	Description	Conditions	Min	Typ	Max	Unit
PFM Mode						
I _{Q_PFM_2PH}	Quiescent current in PFM	V _{IN} = 3.7 V No load No switching		164		µA

Note 1 t_{ON} > 40 ns

3.6 Performance and Supervision Characteristics

Table 9: Electrical Characteristics

Parameter	Description	Conditions	Min	Typ	Max	Unit
Electrical Performance						
V _{THR_POR}	Power-on-reset threshold	Threshold for AVDD falling		2.1	2.25	V
V _{THR_POR_HYS}	Power-on-reset hysteresis			200		mV
T _{WARN}	Thermal warning temperature threshold		115	125	135	°C
T _{CRIT}	Thermal shutdown temperature threshold		130	140	150	°C
I _{IN_OFF}	Supply current	OFF state T _A = 27 °C IC_EN = 0		0.1	1	µA
I _{IN_ON}	Supply current	ON state T _A = 27 °C IC_EN = 1 Buck off	5	10	20	µA

3.7 Digital IO Characteristics

Table 10: Digital I/O Electrical Characteristics

Parameter	Description	Conditions	Min	Typ	Max	Unit
Electrical Performance						
V _{IH_EN}	Input high voltage, IC enable		1.2		AVDD	V
V _{IL_EN}	Input low voltage, IC enable				0.4	V
t _{IC_EN}	IC enable time				1000	µs
V _{IH_GPIO_SCL_SDA}	Input high voltage GPIO, SCL, SDA		1.2		AVDD	V

**High-Performance, 10 A,
Dual-Phase DC-DC Converter**

Parameter	Description	Conditions	Min	Typ	Max	Unit
V _{IL_GPIO_SCL_SDA}	Input low voltage GPIO, SCL, SDA				0.4	V
V _{OH_GPIO}	Output high voltage GPIO	Push-pull mode I _{OUT} = 1 mA	0.8*AV _{DD}		AVDD	V
V _{OL_GPIO}	Output low voltage GPIO	Push-pull mode I _{OUT} = 1 mA			0.2*AV _{DD}	V
V _{OL_SDA}	Output low voltage SDA	I _{OUT} = 3 mA		0.24		V
R _{PD}	GPIO pull-down resistor		2	10	120	kΩ
R _{PU}	GPIO pull-up resistor		2	10	120	kΩ

High-Performance, 10 A, Dual-Phase DC-DC Converter

3.8 Timing Characteristics

Table 11: I2C Electrical Characteristics

Parameter	Description	Conditions	Min	Typ	Max	Unit
Electrical Performance						
t_{BUS}	Bus free time between a STOP and START condition		0.5			μs
C_{BUS}	Bus line capacitive load			150		pF
f_{SCL}	SCL clock frequency		20 Note 1		1000	kHz
t_{LO_SCL}	SCL low time		0.5			μs
t_{HI_SCL}	SCL high time		0.26			μs
t_{RISE}	SCL and SDA rise time	Requirement for input		1000		ns
t_{FALL}	SCL and SDA fall time	Requirement for input		300		ns
t_{SETUP_START}	Start condition setup time		0.26			μs
t_{HOLD_START}	Start condition hold time		0.26			μs
t_{SETUP_STOP}	Stop condition setup time		0.26			μs
t_{DATA}	Data valid time			0.45		μs
t_{DATA_ACK}	Data valid acknowledge time			0.45		μs
t_{SETUP_DATA}	Data setup time		50			ns
t_{HOLD_DATA}	Data hold time		0			ns

Note 1 Minimum clock frequency is limited to 20 kHz if I2C_TIMEOUT is enabled

High-Performance, 10 A, Dual-Phase DC-DC Converter

3.9 Typical Performance

Unless otherwise noted, $V_{IN} = 3.7\text{ V}$, $V_{OUT} = 1.0\text{ V}$, $T_A = 25^\circ\text{C}$, 2.0 mm x 1.6 mm 0.1 μH per-phase output inductors (DCR = typ. 11.5 m Ω) and 4 x 10 μF output capacitors.

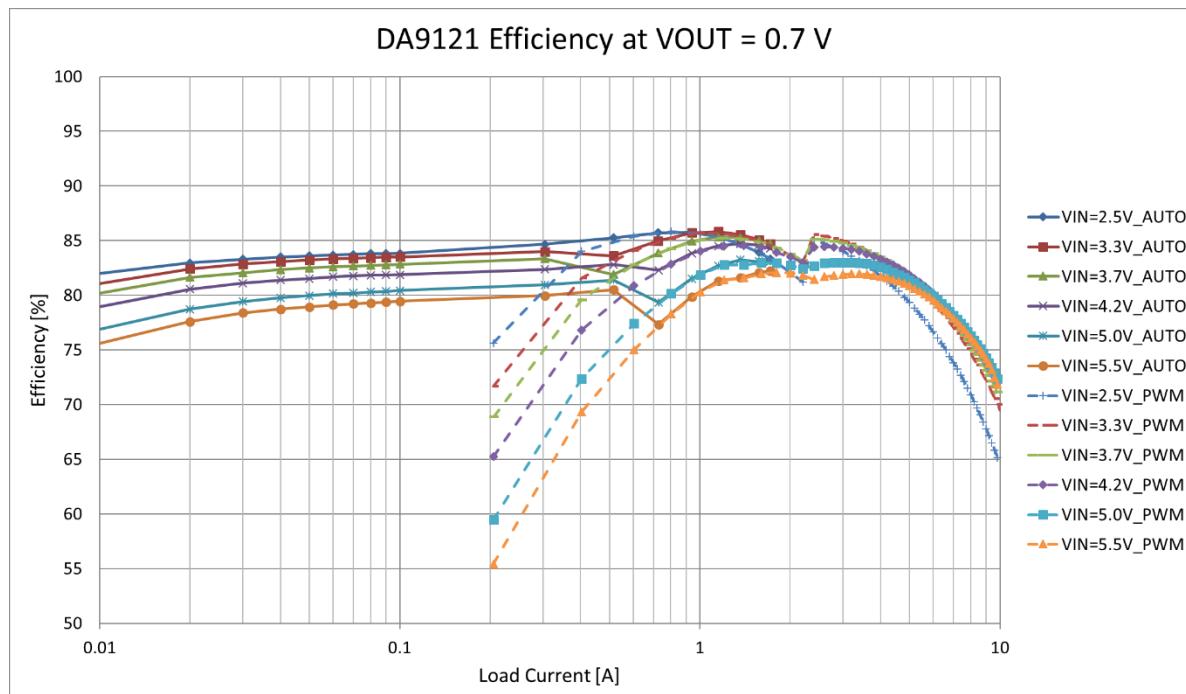


Figure 7: Efficiency v Load, $V_{OUT} = 0.7\text{ V}$

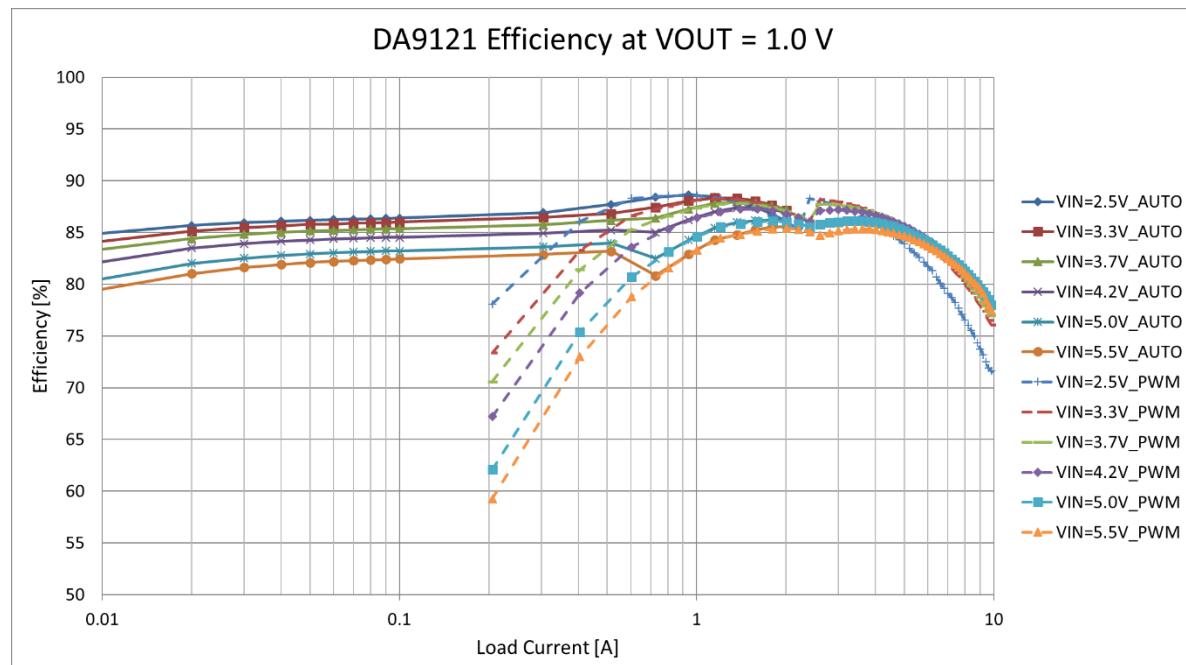
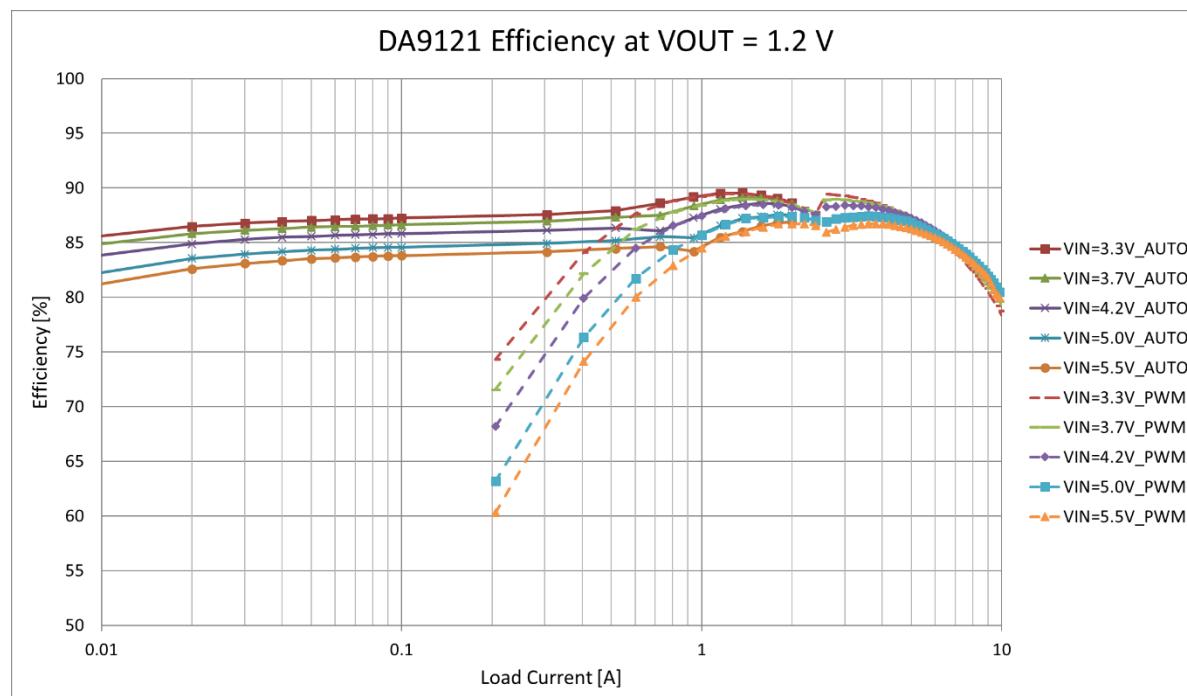
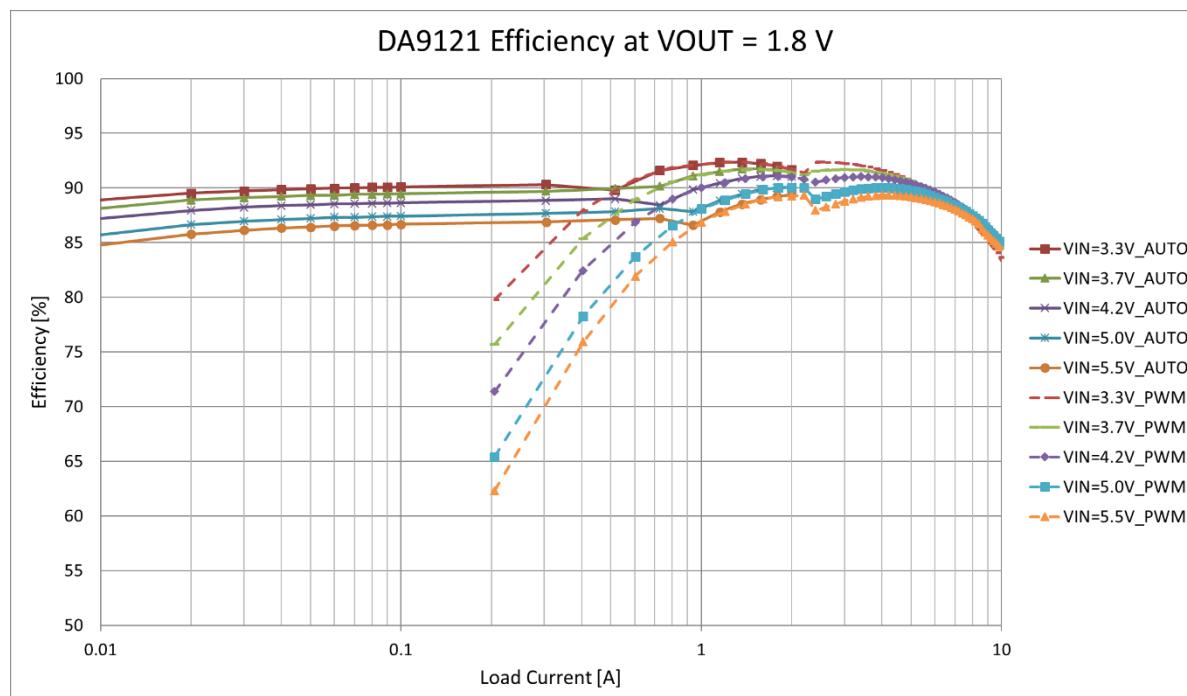
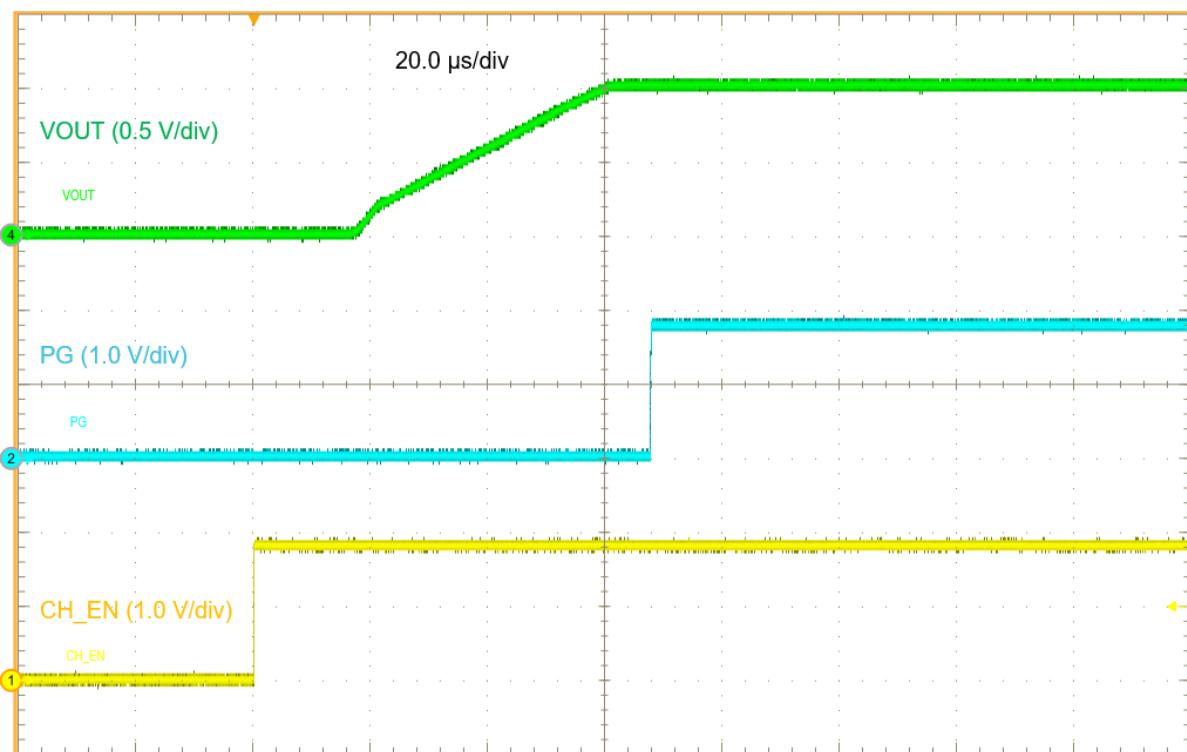
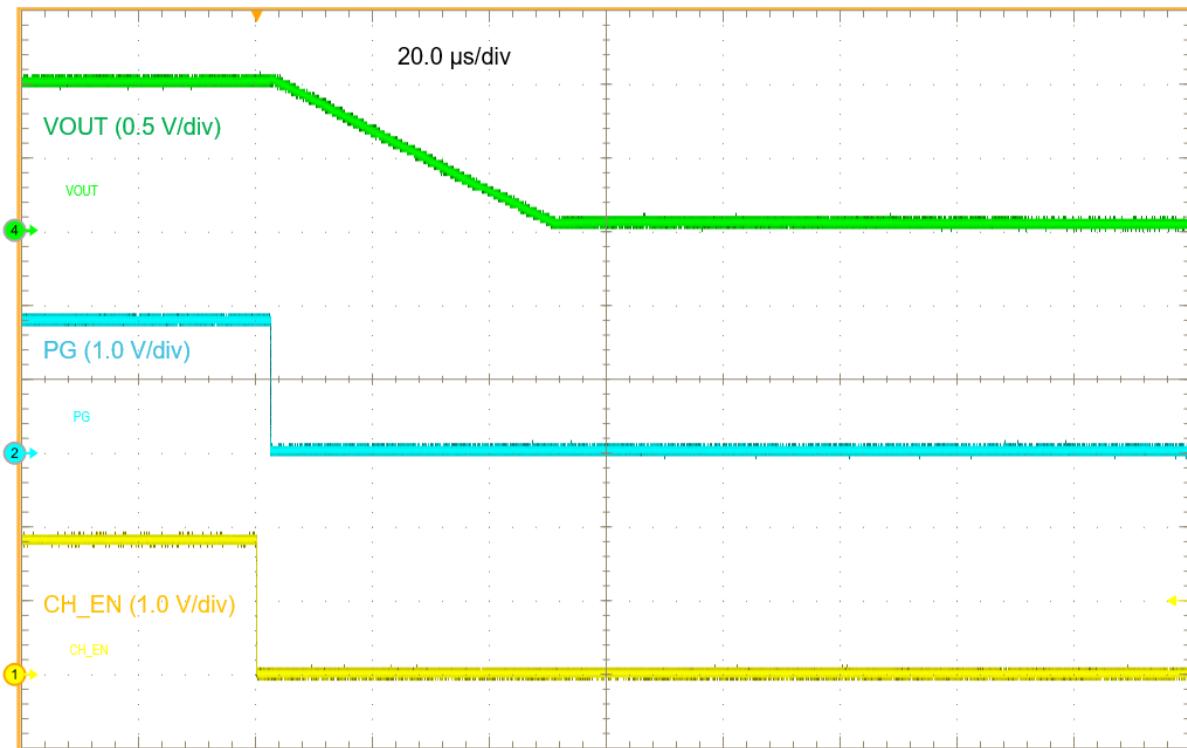
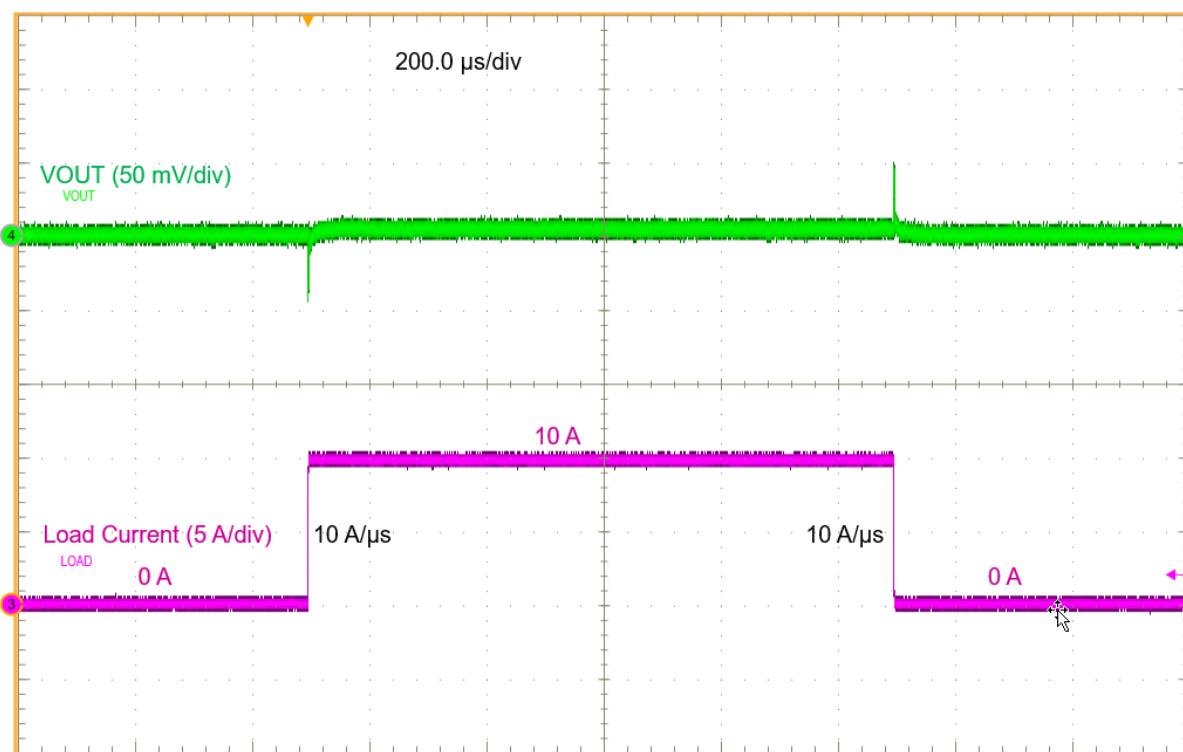
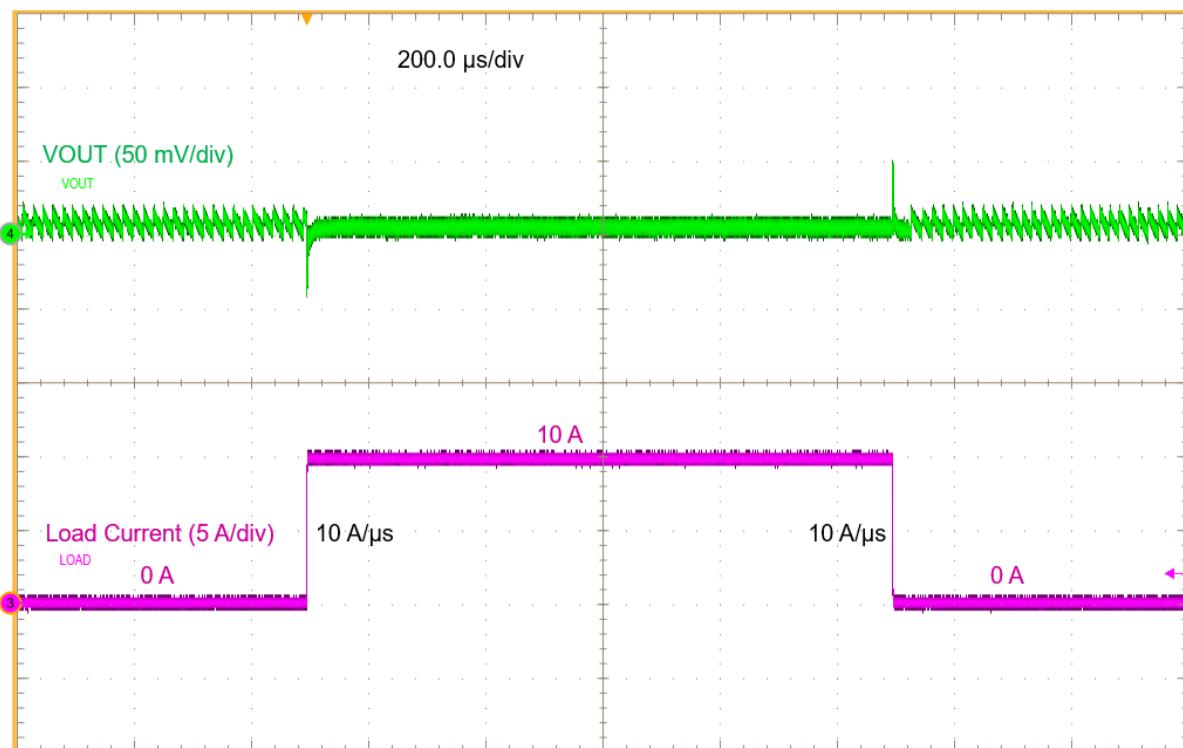


Figure 8: Efficiency vs Load, $V_{OUT} = 1.0\text{ V}$

**High-Performance, 10 A,
Dual-Phase DC-DC Converter****Figure 9: Efficiency vs Load, VOUT = 1.2 V****Figure 10: Efficiency vs Load, VOUT = 1.8 V**

**High-Performance, 10 A,
Dual-Phase DC-DC Converter****Figure 11: Buck Soft Start-up at 20 mV/μs Slew Rate****Figure 12: Buck Active Shutdown at 20 mV/μs Slew Rate**

**High-Performance, 10 A,
Dual-Phase DC-DC Converter****Figure 13: Buck Load Transient Response in PWM Mode, 0 A to 10 A at 10 A/ μ s****Figure 14: Buck Load Transient Response in AUTO Mode, 0 A to 10 A at 10 A/ μ s**

High-Performance, 10 A, Dual-Phase DC-DC Converter

4 Functional Description

4.1 DC-DC Buck Converter

DA9121 operates as a single-channel dual-phase buck converter capable of delivering up to 10 A output current at a 0.3 V to 1.9 V output voltage range.

The buck converter has two voltage registers. One defines the normal output voltage, while the other offers an alternative retention voltage. In this way, different application power modes can easily be supported. The voltage selection can be operated either via GPIO or via control interface to guarantee the maximum flexibility according to the specific host processor status in the application.

When a buck is enabled, its output voltage is monitored and a power good signal indicates that the buck output voltage has reached a level higher than the $V_{THR_PG_RISE}$ threshold. The power good status is lost when the voltage drops below $V_{THR_PG_DWN}$ or increases above V_{THR_HV} . The status of the power good indicator can be read back via I²C from the PG1 status bit. It can be also individually assigned to any of the GPIOs by setting the GPIO mode registers to PG1 output.

The buck converter is capable of supporting DVC transitions that occur when:

- the active and selected A- or B-voltage is updated to a new target value
- the voltage selection is changed from the A- to B-voltage (or B- to A-voltage) using CH1_VSEL

The DVC controller operates in pulse width modulation (PWM) mode with synchronous rectification.

The slew rate of the DVC transition is programmed at 10 mV per 8 μ s, 4 μ s, 2 μ s, 1 μ s, or 0.5 μ s in register bits CH1_SR_DVC.

A pull-down resistor (typically 150 Ω) for each phase is always activated unless it is disabled by setting register bits CH1_PD_DIS to 1.

4.1.1 Switching Frequency

The buck switching frequency can be tuned using register bit OSC_TUNE. The internal 8 MHz oscillator frequency is tuned in ± 160 kHz steps. This impacts the buck converter frequency in steps of 80 kHz and helps to mitigate possible disturbances to other high frequency systems in the application.

4.1.2 Operation Modes and Phase Selection

The buck converters can operate in PWM and PFM modes. The operating mode is selected using register bits CH1_<A or B>_MODE.

Phase shedding automatically changes between 1- and 2-phase operation at a typical current of 2.0 A.

If the automatic operation mode is selected on CH1_<A or B>_MODE, the buck converter automatically changes between synchronous PWM mode and PFM depending on the load current. This improves the efficiency across the whole range of output load currents.

High-Performance, 10 A, Dual-Phase DC-DC Converter

4.1.3 Output Voltage Selection

The switching converter can be configured using the I²C interface.

Two output voltages can be pre-configured in registers CH1_<A or B>_VOUT. The output voltage can be selected by either toggling register bit CH1_VSEL or by re-programming the selected voltage control register. Both changes will result in ramped voltage transitions. After being enabled, the buck converter will, by default, use the register settings in CH1_A_VOUT unless the output voltage selection is configured via the GPIO port.

Registers CH1_VMAX limit the output voltage that can be set for each of the respective buck converters.

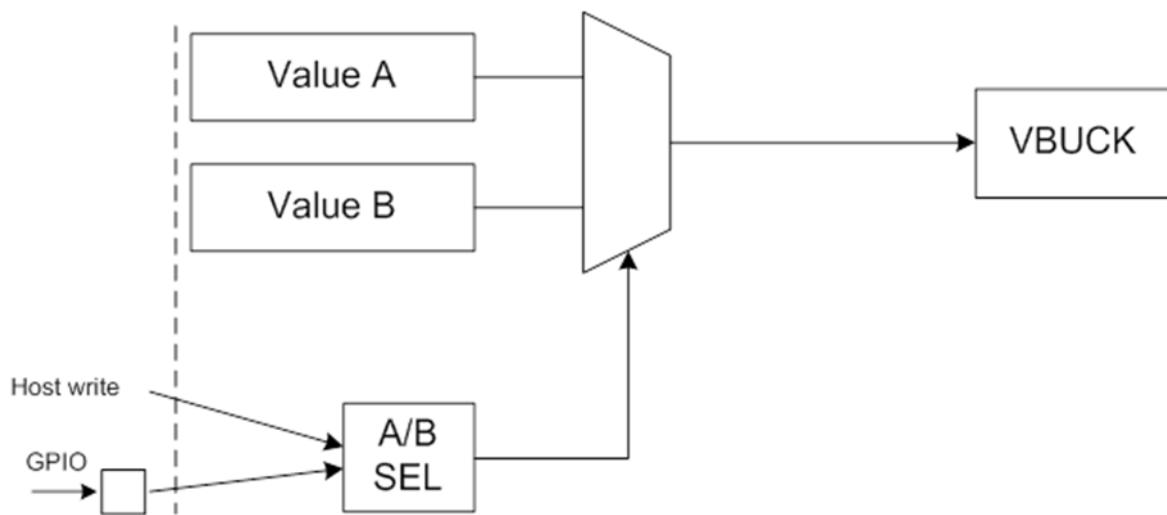


Figure 15: Buck Output Voltage Control Concept

4.1.4 Soft Start-Up and Shutdown

To limit in-rush current from VSYS, the buck converter can perform a soft-start after being enabled. The start-up behavior is a compromise between acceptable inrush current from the battery and turn-on time. Ramp times can be configured in register CH1_SR_STARTUP. Rates higher than 20 mV/μs may produce overshoot during the start-up phase, so it should be considered carefully.

A ramped power down can be selected in register bits CH1_SR_SHDN. When no ramp is selected (immediate power down), the output node will be discharged only by the pull-down resistor, if enabled in register CH1_PD_DIS.

4.1.5 Current Limit

The integrated current limit protects the power stages and external coil from excessive current. The buck current limit should be configured to at least 40 % higher than the required maximum output current.

When the current limit is reached, the buck converter generates an event and an interrupt to the host processor unless the interrupt has been masked using register M_OC1 in SYS_MASK_1. Register bit OC_DVC_MASK is used to mask over-current events during DVC transitions.

High-Performance, 10 A, Dual-Phase DC-DC Converter

4.1.6 Thermal Protection

DA9121 is protected from internal overheating by thermal shutdown.

There are two kinds of flags concerning thermal protection, thermal warning and thermal critical. The warning flag is asserted when $T_J > T_{\text{WARN}}$ and the critical flag is asserted when $T_J > T_{\text{CRIT}}$. When the critical flag is asserted, Buck1 is shut down immediately.

Table 12: Thermal Protection Control Registers

Category	Register name	Description
Status	TEMP_WARN	Asserted as long as the thermal warning threshold is reached
	TEMP_CRIT	Asserted as long as the thermal shutdown threshold is reached
IRQ event	E_TEMP_WARN	TEMP_WARN caused event
	E_TEMP_CRIT	TEMP_CRIT caused event
IRQ mask	M_TEMP_WARN	TEMP_WARN event IRQ mask
	M_TEMP_CRIT	TEMP_CRIT event IRQ mask
	M_VR_HOT	TEMP_WARN status IRQ mask

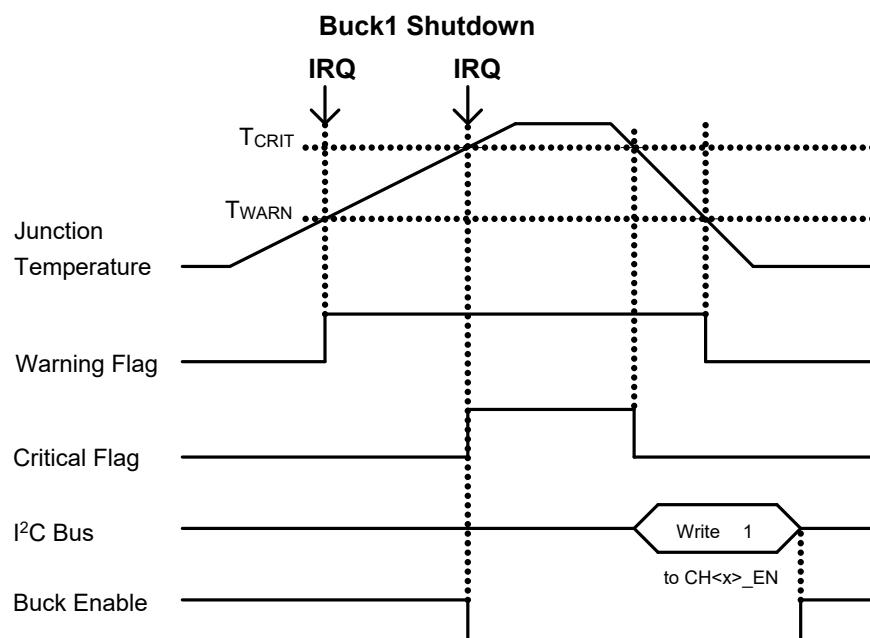


Figure 16: Thermal Protection Operation

High-Performance, 10 A, Dual-Phase DC-DC Converter

4.2 Internal Circuits

4.2.1 IC_EN/Chip Enable/Disable

IC_EN is chip enable/disable control input. When IC_EN = 0, all blocks except for low I_Q POR are powered-down and buck output is pulled-down.

4.2.2 nIRQ/Interrupt

The interrupt triggers events. Trigger conditions and control registers for each interrupt event are listed in [Table 13](#).

Some of these events are categorized as fault events and affect device operation (for example, buck disable), see Section [4.1.6](#).

Table 13: Interrupt List

Name	Polarity (Note 1)	Trigger	IRQ Status Register	IRQ Mask Register	Deglitch Period
Thermal warning (event)	N	T_J rising above T_{WARN}	E_TEMP_WARN	M_TEMP_WARN	0 s
Thermal critical (event)	N	T_J rising above T_{CRIT}	E_TEMP_CRIT	M_TEMP_CRIT	0 s
Buck1 power-good (event)	P	Buck1 V_{OUT} is in power-good voltage range (not under- or over-voltage)	E_PG1	M_PG1	0 s
Buck1 over-voltage (event)	N	Buck1 V_{OUT} rising above over-voltage threshold (target voltage + 150 mV)	E_OV1	M_OV1	Rise:8 μ s Fall:8 μ s
Buck1 under-voltage (event)	N	Buck1 V_{OUT} falling below under-voltage threshold (target voltage - V_{TH_PG})	E_UV1	M_UV1	0 s
Buck1 over-current (event)	N	Buck1 current rising above over-current threshold	E_OC1	M_OC1	0 s
Buck1 power-good (status) (Note 2)	P	Buck1 V_{OUT} is in power-good voltage range (not under- or over-voltage)	PG1	M_PG1_STAT (Note 3)	0 s
Thermal warning (status) (Note 2)	N	T_J rising above T_{WARN}	TEMP_WARN	M_VR_HOT (Note 3)	0 s
GPIO0 change (event)	N	Detect GPIO0 change for active trigger selected GPIO0_TRIG register	E_GPIO0	M_GPIO0	100 μ s/ 1 ms/ 10 ms/ 100 ms
GPIO1 change (event)	N	Detect GPIO1 change for active trigger selected GPIO1_TRIG register	E_GPIO1	M_GPIO1	

High-Performance, 10 A, Dual-Phase DC-DC Converter

Name	Polarity (Note 1)	Trigger	IRQ Status Register	IRQ Mask Register	Deglitch Period
GPIO2 change (event)	N	Detect GPIO2 change for active trigger selected GPIO2_TRIG register	E_GPIO2	M_GPIO2	

Note 1 Polarity at the source of the flag: P = active-high, N = active-low.

General rule is: normal system state is high, and abnormal system state is low (for example, PG = high means power-good, TEMP_CRIT = low when TEMP critical state).

Note 2 Interrupt outputs the status as is. I²C write is not required for interrupt clear.

Note 3 OTP load value defined by CONF pin setting if CONF_EN = 1.

Table 14: Interrupt Registers Except for Power Good Status

Register	Description
E_<name>	Read-only interrupt event register 0: No interrupt 1: Interrupt occurred Cleared after being written to I²C. Set until IRQ is removed.
M_<name>	Interrupt mask register 0: Not masked 1: Masked. No IRQ signal sent. Event register (E_<name>) is updated.

Table 15: Interrupt Registers for Power Good and Temp Warning Status

Register	Description
PG<x>	Buck<x> power good status. Asserted as long as the buck<x> output voltage is in range (under-voltage threshold < buck output voltage < over-voltage threshold) 0: Not power good 1: Power good
M_PG<x>_STAT	Power good status interrupt mask register 0: Not masked 1: Masked. No IRQ signal sent. Power good status register (PG<x>) is updated
TEMP_WARN	Asserted as long as the thermal warning threshold (T _{WARN}) is reached 0: Junction temperature is below T _{WARN} 1: Junction temperature is above T _{WARN}
M_VR_HOT	Temperature warning status (TEMP_WARN) interrupt mask register 0: Not masked 1: Masked. No IRQ signal sent. Temperature warning status register (TEMP_WARN) is updated

High-Performance, 10 A, Dual-Phase DC-DC Converter

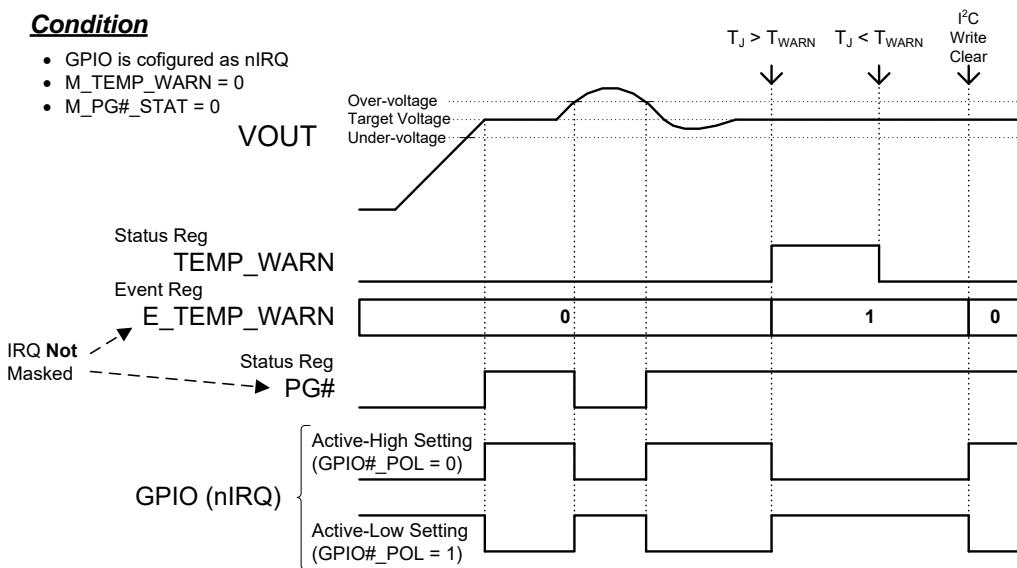


Figure 17: Interrupt Operation Example

High-Performance, 10 A, Dual-Phase DC-DC Converter

4.2.3 GPIO

4.2.3.1 GPIO Pin Assignment

The DA9121 provides up to five GPIO pins, three if the I²C is enabled, see [Table 16](#). These registers are OTP programmable. When CONF_EN = 1 GPIO0 can be used for chip configuration.

Any register settings for GPIO3 and GPIO4 are ignored and GPIO3 and GPIO4 function as SCL and SDA respectively if I²C_EN = 1.

Table 16: GPIO Pin Assignment

OTP Option		GPIO Pin					Available GPIOs
I ² C_EN	CONF_EN	CONF/ GPIO0	GPIO1	GPIO2	SCL/ GPIO3	SDA/ GPIO4	
1'b0	1'b0	GPIO0	GPIO1	GPIO2	GPIO3	GPIO4	5
	1'b1	CONF	GPIO1	GPIO2	GPIO3	GPIO4	4
1'b1	1'b0	GPIO0	GPIO1	GPIO2	SCL	SDA	3
	1'b1	CONF	GPIO1	GPIO2	SCL	SDA	2

4.2.3.2 GPIO Function

The GPIOs pins are configurable as the following functions in register GPIO<x>_MODE (x = 0 to 4):

- Buck1 enable input (EN1)
- Buck1 DVC control input (DVC1)
- Buck1 OTP setting reload input (RELOAD)
- Buck1 power good output (PG1)
- Interrupt output (nIRQ)

Table 17: GPIO Function Configuration

GPIO<x>_MODE[3:0]	Function	IO Condition
4'h0	GPIO disable	HiZ
4'h1	EN1	In
4'h2	Reserved	In
4'h3	Reserved	In
4'h4	DVC1	In
4'h5	Reserved	In
4'h6	Reserved	In
4'h7	RELOAD	In
4'h8	PG1	Out
4'h9	Reserved	Out
4'hA	Reserved	Out
4'hB	Reserved	Out
4'hC	nIRQ	Out
4'hD	Reserved	HiZ
4'hE	Low level	Out
4'hF	High level	Out

High-Performance, 10 A, Dual-Phase DC-DC Converter

4.2.3.3 Chip Configuration Select (CONF)

GPIO0 functions as chip configuration select (CONF) input when CONF_EN = 1.

Three different chip configurations can be selected according to the CONF pin level, whether it is HIGH, LOW, or Hi-Z.

Table 18: GPIO0-Configurable Registers when CONF_EN = 1

Register Name	Description
IF_SLAVE_ADDR[6:0]	I2C slave address
CH1_A_MODE[1:0]	CH1_A Operation mode select
CH1_B_MODE[1:0]	CH1_B Operation mode select
CH1_VSEL	CH1 output voltage and operation selection
CH1_EN	CH1 enable
CH1_A_VOUT[7:0]	CH1 output voltage setting A
CH1_B_VOUT[7:0]	CH1 output voltage setting B
M_PG1_STAT	IRQ mask setting for CH1 power good status
M_VR_HOT	IRQ mask setting for temp warning status
GPIO1_MODE[3:0]	GPIO1 mode setting
GPIO2_MODE[3:0]	GPIO2 mode setting
GPIO1_OBUF	GPIO1 output buffer select
GPIO2_OBUF	GPIO2 output buffer select
GPIO1_TRIG[1:0]	GPIO1 input trigger select
GPIO1_POL	GPIO1 polarity select
GPIO1_PUPD	GPIO1 pull-up/pull-down enable
GPIO1_DEB[1:0]	GPIO1 input debounce time setting
GPIO1_DEB_RISE	GPIO1 input debounce rising edge enable
GPIO1_DEB_FALL	GPIO1 input debounce falling edge enable
GPIO2_TRIG[1:0]	GPIO2 input trigger select
GPIO2_POL	GPIO2 polarity select
GPIO2_PUPD	GPIO2 pull-up/pull-down enable
GPIO2_DEB[1:0]	GPIO2 input debounce time setting
GPIO2_DEB_RISE	GPIO2 input debounce rising edge enable
GPIO2_DEB_FALL	GPIO2 input debounce falling edge enable

4.2.3.4 OTP Reload (RELOAD)

Buck settings listed in **Error! Reference source not found.** are reloaded from CONF registers by triggering GPIO configured as RELOAD input.

The OTP reload happens at the same time for Buck1 settings. During reloading, Buck1 keeps operating as configured without shut-down.

High-Performance, 10 A, Dual-Phase DC-DC Converter

Table 19: OTP Reload Registers

Register Name	Description
CH#_VSEL	CH# output voltage and operation selection. 0: A, 1: B
CH#_A_VOUT[7:0]	CH# output voltage setting A : CH#_A_VOUT * 10 mV Setting under 0.3V is clamped to 0.3V, and setting over 1.9V is clamped to 1.9 V
CH#_B_VOUT[7:0]	CH# output voltage setting B : CH#_A_VOUT * 10 mV Setting under 0.3 V is clamped to 0.3 V, and setting over 1.9V is clamped to 1.9 V
CH#_A_MODE[1:0]	Operation mode selection 0: Force PFM 1: Force PWM. full phase 2: Force PWM with phase shedding 3: Auto mode
CH#_B_MODE[1:0]	Operation mode selection 0: Force PFM 1: Force PWM. full phase 2: Force PWM with phase shedding 3: Auto mode

4.3 Operating Modes

4.3.1 ON

DA9121 is ON when the IC_EN port is higher than V_{IH_EN} and the supply voltage is higher than V_{THR_POR} . Once enabled, the host processor can start communicating with DA9121 using the control interface, after the t_{IC_EN} delay.

4.3.2 OFF

DA9121 is OFF when the IC_EN port is lower than V_{IL_EN} . In OFF, the bucks are always disabled and LX nodes are pulled down by (typically 150 Ω) internal pull-down resistors.

4.4 I²C Communication

All features of DA9121 can be controlled with the I²C interface which is enabled or disabled in register I2C_EN.

I2C_EN	Description
0	I ² C disable: SCL/GPIO3 and SDA/GPIO4 pins can be used as GPIO
1	I ² C enable: SCL/GPIO3 and SDA/GPIO4 pins are used as I ² C clock input and I ² C data input/output.

GPIO3 functions as the I²C clock and GPIO4 carries all the power manager bidirectional I²C data. The I²C interface is open-drain supporting multiple devices on a single line. The bus lines have to be pulled high by external pull-up resistors (2 k Ω to 20 k Ω). The standard frequency of the I²C bus is 1 MHz in fast-mode plus (FM+), 400 kHz in fast-mode, or 100 kHz in standard mode.

4.4.1 I²C Protocol

All data is transmitted across the I²C bus in eight-bit groups. To send a bit, the SDA line is driven towards the intended state while the SCL is low (a low SDA indicates a zero bit). Once the SDA has

High-Performance, 10 A, Dual-Phase DC-DC Converter

settled, the SCL line is brought high and then low. This pulse on SCL clocks the SDA bit into the receiver's shift register.

A two-byte serial protocol is used containing one byte for address and one byte data. Data and address transfer are transmitted MSB first for both read and write operations. All transmissions begin with the START condition from the master while the bus is in idle state (the bus is free). It is initiated by a high to low transition on the SDA line while the SCL is in the high state (a STOP condition is indicated by a low to high transition on the SDA line while the SCL is in the high state).



Figure 18: I²C START and STOP Condition Timing

The I²C bus is monitored for a valid slave address whenever the interface is enabled. It responds immediately when it receives its own slave address. The acknowledge is done by pulling the SDA line low during the following clock cycle (white blocks marked with A in Figure 19 and Figure 20).

The protocol for a register write from master to slave consists of a START condition, a slave address with read/write bit, and the eight-bit register address followed by eight bits of data, terminated by a STOP condition. DA9121 responds to all bytes with acknowledge (A), see Figure 19.

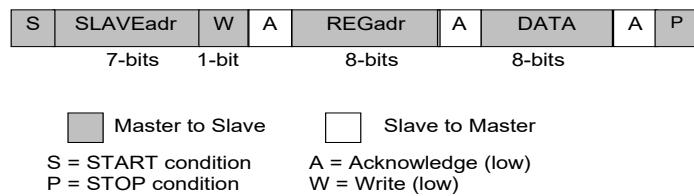


Figure 19: I²C Byte Write (SDA Line)

High-Performance, 10 A, Dual-Phase DC-DC Converter

When the host reads data from a register it first has to write to DA9121 with the target register address and then read from DA9121 with a repeated START, or alternatively a second START, condition. After receiving the data, the host sends no acknowledge (A^*) and terminates the transmission with a STOP condition, see [Figure 20](#).

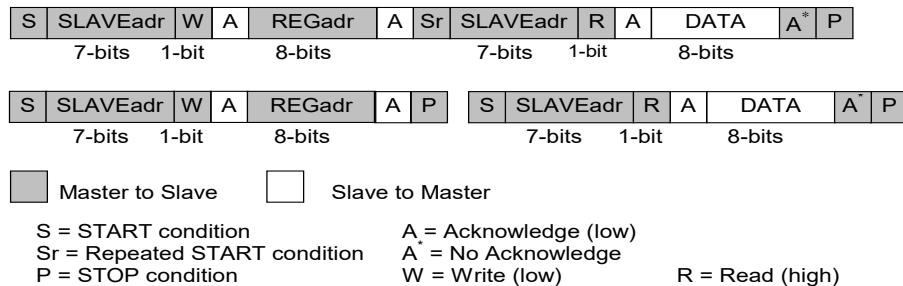


Figure 20: I²C Byte Read (SDA Line) Examples

High-Performance, 10 A, Dual-Phase DC-DC Converter

5 Register Definitions

5.1 Register Map

Table 20: Register Map

Addr	Register	7	6	5	4	3	2	1	0
System Module									
System									
0x0001	SYS_STATUS_0	Reserved	Reserved	Reserved	Reserved	Reserved	Reserved	TEMP_CRIT	TEMP_WA_RN
0x0002	SYS_STATUS_1	Reserved	Reserved	Reserved	Reserved	PG1	OV1	UV1	OC1
0x0003	SYS_STATUS_2	Reserved	Reserved	Reserved	Reserved	Reserved	GPIO2	GPIO1	GPIO0
0x0004	SYS_EVENT_0	Reserved	Reserved	Reserved	Reserved	Reserved	Reserved	E_TEMP_C_RIT	E_TEMP_WARN
0x0005	SYS_EVENT_1	Reserved	Reserved	Reserved	Reserved	E_PG1	E_OV1	E_UV1	E_OC1
0x0006	SYS_EVENT_2	Reserved	Reserved	Reserved	Reserved	Reserved	E_GPIO2	E_GPIO1	E_GPIO0
0x0007	SYS_MASK_0	Reserved	Reserved	Reserved	Reserved	Reserved	Reserved	M_TEMP_C_RIT	M_TEMP_WARN
0x0008	SYS_MASK_1	Reserved	Reserved	Reserved	Reserved	M_PG1	M_OV1	M_UV1	M_OC1
0x0009	SYS_MASK_2	Reserved	Reserved	Reserved	Reserved	Reserved	M_GPIO2	M_GPIO1	M_GPIO0
0x000A	SYS_MASK_3	Reserved	Reserved	Reserved	Reserved	M_VR_HO_T	Reserved	Reserved	M_PG1_ST_AT
0x000B	SYS_CONFIG_0	Reserved				Reserved			
0x000C	SYS_CONFIG_1	Reserved				Reserved			
0x000D	SYS_CONFIG_2	Reserved	OC_LATCHOFF<1:0>	OC_DVC_MASK		PG_DVC_MASK<1:0>		Reserved	Reserved
0x000E	SYS_CONFIG_3	Reserved	OSC_TUNE<2:0>			Reserved	Reserved	I2C_TIMEO_UT	Reserved
0x0010	SYS_GPIO0_0	Reserved	Reserved	Reserved	GPIO0_MODE<3:0>				GPIO0_OB_UF
0x0011	SYS_GPIO0_1	GPIO0_D_EB_FALL	GPIO0_D_EB_RISE	GPIO0_DEB<1:0>		GPIO0_P_UPD	GPIO0_POL	GPIO0_TRIG<1:0>	
0x0012	SYS_GPIO1_0	Reserved	Reserved	Reserved	GPIO1_MODE<3:0>				GPIO1_OB_UF
0x0013	SYS_GPIO1_1	GPIO1_D_EB_FALL	GPIO1_D_EB_RISE	GPIO1_DEB<1:0>		GPIO1_P_UPD	GPIO1_POL	GPIO1_TRIG<1:0>	
0x0014	SYS_GPIO2_0	Reserved	Reserved	Reserved	GPIO2_MODE<3:0>				GPIO2_OB_UF
0x0015	SYS_GPIO2_1	GPIO2_D_EB_FALL	GPIO2_D_EB_RISE	GPIO2_DEB<1:0>		GPIO2_P_UPD	GPIO2_POL	GPIO2_TRIG<1:0>	

High-Performance, 10 A, Dual-Phase DC-DC Converter

Addr	Register	7	6	5	4	3	2	1	0					
Buck Control														
Buck1														
0x0020	BUCK_BUCK1_0	Reserved	CH1_SR_DVC_DWN<2:0>			CH1_SR_DVC_UP<2:0>		CH1_EN						
0x0021	BUCK_BUCK1_1	Reserved	CH1_SR_SHDN<2:0>			CH1_SR_STARTUP<2:0>		CH1_PD_D IS						
0x0022	BUCK_BUCK1_2	Reserved	Reserved	Reserved	Reserved	CH1_ILIM<3:0>								
0x0023	BUCK_BUCK1_3	CH1_VMAX<7:0>												
0x0024	BUCK_BUCK1_4	Reserved	Reserved	Reserved	CH1_VSE L	CH1_B_MODE<1:0>		CH1_A_MODE<1:0>						
0x0025	BUCK_BUCK1_5	CH1_A_VOUT<7:0>												
0x0026	BUCK_BUCK1_6	CH1_B_VOUT<7:0>												
0x0027	BUCK_BUCK1_7	Reserved	Reserved	Reserved	Reserved	Reserved	Reserved	Reserved	Reserved					
Serialization														
0x0048	OTP_DEVICE_ID	DEV_ID<7:0>												
0x0049	OTP_VARIANT_ID	MRC<3:0>			VRC<3:0>									
0x004A	OTP_CUSTOMER_ID	CUST_ID<7:0>												
0x004B	OTP_CONFIG_ID	CONFIG_REV<7:0>												

High-Performance, 10 A, Dual-Phase DC-DC Converter

5.1.1 System

Table 21: SYS_STATUS_0 (0x0001)

Bit	Symbol	Description
[1]	TEMP_CRIT	Asserted as long as the thermal shutdown threshold is reached
[0]	TEMP_WARN	Asserted as long as the thermal warning threshold is reached

Table 22: SYS_STATUS_1 (0x0002)

Bit	Symbol	Description
[3]	PG1	Asserted as long as the Buck1 output voltage is in range
[2]	OV1	Asserted as long as Buck1 hitting over-voltage
[1]	UV1	Asserted as long as Buck1 hitting under-voltage
[0]	OC1	Asserted as long as Buck1 hitting over-current

Table 23: SYS_STATUS_2 (0x0003)

Bit	Symbol	Description
[2]	GPIO2	GPIO2 status
[1]	GPIO1	GPIO1 status
[0]	GPIO0	GPIO0 status

Table 24: SYS_EVENT_0 (0x0004)

Bit	Symbol	Description
[1]	E_TEMP_CRIT	TEMP_CRIT caused event. Writing 1 action clear this bit into 0 if event source has been released.
[0]	E_TEMP_WARN	TEMP_WARN caused event. Writing 1 action clear this bit into 0 if event source has been released.

Table 25: SYS_EVENT_1 (0x0005)

Bit	Symbol	Description
[3]	E_PG1	PG1 caused event. Writing 1 action clear this bit into 0 if event source has been released.
[2]	E_OV1	OV1 caused event. Writing 1 action clear this bit into 0 if event source has been released.
[1]	E_UV1	UV1 caused event. Writing 1 action clear this bit into 0 if event source has been released.
[0]	E_OC1	OC1 caused event. Writing 1 action clear this bit into 0 if event source has been released.

**High-Performance, 10 A,
Dual-Phase DC-DC Converter**
Table 26: SYS_EVENT_2 (0x0006)

Bit	Symbol	Description
[2]	E_GPIO2	GPIO2 event. Writing 1 action clear this bit into 0 if event source has been released.
[1]	E_GPIO1	GPIO1 event. Writing 1 action clear this bit into 0 if event source has been released.
[0]	E_GPIO0	GPIO0 event. Writing 1 action clear this bit into 0 if event source has been released.

Table 27: SYS_MASK_0 (0x0007)

Bit	Symbol	Description
[1]	M_TEMP_CRIT	TEMP_CRIT IRQ mask
[0]	M_TEMP_WARN	TEMP_WARN IRQ mask

Table 28: SYS_MASK_1 (0x0008)

Bit	Symbol	Description
[3]	M_PG1	PG1 event IRQ mask
[2]	M_OV1	OV1 event IRQ mask
[1]	M_UV1	UV1 event IRQ mask
[0]	M_OC1	OC1 event IRQ mask

Table 29: SYS_MASK_2 (0x0009)

Bit	Symbol	Description
[2]	M_GPIO2	GPIO2 IRQ mask
[1]	M_GPIO1	GPIO1 IRQ mask
[0]	M_GPIO0	GPIO0 IRQ mask

Table 30: SYS_MASK_3 (0x000A)

Bit	Symbol	Description
[3]	M_VR_HOT	Temp warning status IRQ mask. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1
[0]	M_PG1_STAT	PG1 status IRQ mask. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1

**High-Performance, 10 A,
Dual-Phase DC-DC Converter**
Table 31: SYS_CONFIG_2 (0x000D)

Bit	Symbol	Description										
[6:5]	OC_LATCHOFF	<p>Over-current latch-off setting. BUCK shut-down after OCP for 8 μs/1 ms/3 ms unless disable setting. IRQ is generated unless IRQ is masked.</p> <table> <thead> <tr> <th>Value</th><th>Description</th></tr> </thead> <tbody> <tr> <td>0x0</td><td>Latch off disable</td></tr> <tr> <td>0x1</td><td>Latch off after 8 μs of OCP signal</td></tr> <tr> <td>0x2</td><td>Latch off after 1 ms of OCP signal</td></tr> <tr> <td>0x3</td><td>Latch off after 3 ms of OCP signal</td></tr> </tbody> </table>	Value	Description	0x0	Latch off disable	0x1	Latch off after 8 μ s of OCP signal	0x2	Latch off after 1 ms of OCP signal	0x3	Latch off after 3 ms of OCP signal
Value	Description											
0x0	Latch off disable											
0x1	Latch off after 8 μ s of OCP signal											
0x2	Latch off after 1 ms of OCP signal											
0x3	Latch off after 3 ms of OCP signal											
[4]	OC_DVC_MASK	Over-current event (IRQ and latch-off feature) mask during DVC ramp-up and ramp-down										
[3:2]	PG_DVC_MASK	<p>Power-good mask during DVC</p> <table> <thead> <tr> <th>Value</th><th>Description</th></tr> </thead> <tbody> <tr> <td>0x0</td><td>No mask</td></tr> <tr> <td>0x1</td><td>Mask as not power good during DVC</td></tr> <tr> <td>0x2</td><td>Mask as power good during DVC</td></tr> <tr> <td>0x3</td><td>Reserved</td></tr> </tbody> </table>	Value	Description	0x0	No mask	0x1	Mask as not power good during DVC	0x2	Mask as power good during DVC	0x3	Reserved
Value	Description											
0x0	No mask											
0x1	Mask as not power good during DVC											
0x2	Mask as power good during DVC											
0x3	Reserved											

Table 32: SYS_CONFIG_3 (0x000E)

Bit	Symbol	Description																		
[6:4]	OSC_TUNE	<p>Tune oscillator frequency, tuned frequency = Current + OSC_TUNE * 160 kHz</p> <table> <thead> <tr> <th>Value</th><th>Description</th></tr> </thead> <tbody> <tr> <td>0x3</td><td>3</td></tr> <tr> <td>0x2</td><td>2</td></tr> <tr> <td>0x1</td><td>1</td></tr> <tr> <td>0x0</td><td>0</td></tr> <tr> <td>0x7</td><td>-1</td></tr> <tr> <td>0x6</td><td>-2</td></tr> <tr> <td>0x5</td><td>-3</td></tr> <tr> <td>0x4</td><td>-4</td></tr> </tbody> </table>	Value	Description	0x3	3	0x2	2	0x1	1	0x0	0	0x7	-1	0x6	-2	0x5	-3	0x4	-4
Value	Description																			
0x3	3																			
0x2	2																			
0x1	1																			
0x0	0																			
0x7	-1																			
0x6	-2																			
0x5	-3																			
0x4	-4																			
[1]	I2C_TIMEOUT	Enable automatic reset of 2-wire interface (if SDA stays low for >50 ms).																		

**High-Performance, 10 A,
Dual-Phase DC-DC Converter**
Table 33: SYS_GPIO0_0 (0x0010)

Bit	Symbol	Description																																		
[4:1]	GPIO0_MODE	<p>GPIO function mode select</p> <table> <thead> <tr> <th>Value</th> <th>Description</th> </tr> </thead> <tbody> <tr> <td>0x0</td> <td>GPIO disable</td> </tr> <tr> <td>0x1</td> <td>EN1 input</td> </tr> <tr> <td>0x2</td> <td>Reserved</td> </tr> <tr> <td>0x3</td> <td>Reserved</td> </tr> <tr> <td>0x4</td> <td>DVC1 input</td> </tr> <tr> <td>0x5</td> <td>Reserved</td> </tr> <tr> <td>0x6</td> <td>Reserved</td> </tr> <tr> <td>0x7</td> <td>RELOAD input</td> </tr> <tr> <td>0x8</td> <td>PG1 output</td> </tr> <tr> <td>0x9</td> <td>Reserved</td> </tr> <tr> <td>0xA</td> <td>Reserved</td> </tr> <tr> <td>0xB</td> <td>Reserved</td> </tr> <tr> <td>0xC</td> <td>nIRQ output</td> </tr> <tr> <td>0xD</td> <td>Reserved</td> </tr> <tr> <td>0xE</td> <td>Low output</td> </tr> <tr> <td>0xF</td> <td>High output</td> </tr> </tbody> </table>	Value	Description	0x0	GPIO disable	0x1	EN1 input	0x2	Reserved	0x3	Reserved	0x4	DVC1 input	0x5	Reserved	0x6	Reserved	0x7	RELOAD input	0x8	PG1 output	0x9	Reserved	0xA	Reserved	0xB	Reserved	0xC	nIRQ output	0xD	Reserved	0xE	Low output	0xF	High output
Value	Description																																			
0x0	GPIO disable																																			
0x1	EN1 input																																			
0x2	Reserved																																			
0x3	Reserved																																			
0x4	DVC1 input																																			
0x5	Reserved																																			
0x6	Reserved																																			
0x7	RELOAD input																																			
0x8	PG1 output																																			
0x9	Reserved																																			
0xA	Reserved																																			
0xB	Reserved																																			
0xC	nIRQ output																																			
0xD	Reserved																																			
0xE	Low output																																			
0xF	High output																																			
[0]	GPIO0_OBUF	<p>GPIO output buffer select</p> <table> <thead> <tr> <th>Value</th> <th>Description</th> </tr> </thead> <tbody> <tr> <td>0x0</td> <td>open-drain output</td> </tr> <tr> <td>0x1</td> <td>push-pull output</td> </tr> </tbody> </table>	Value	Description	0x0	open-drain output	0x1	push-pull output																												
Value	Description																																			
0x0	open-drain output																																			
0x1	push-pull output																																			

Table 34: SYS_GPIO0_1 (0x0011)

Bit	Symbol	Description										
[7]	GPIO0_DEB_FALL	GPI debounce falling edge										
[6]	GPIO0_DEB_RISE	GPI debounce rising edge										
[5:4]	GPIO0_DEB	<p>GPI debounce time</p> <table> <thead> <tr> <th>Value</th> <th>Description</th> </tr> </thead> <tbody> <tr> <td>0x0</td> <td>100 µs debounce</td> </tr> <tr> <td>0x1</td> <td>1 ms debounce</td> </tr> <tr> <td>0x2</td> <td>10 ms debounce</td> </tr> <tr> <td>0x3</td> <td>100 ms debounce</td> </tr> </tbody> </table>	Value	Description	0x0	100 µs debounce	0x1	1 ms debounce	0x2	10 ms debounce	0x3	100 ms debounce
Value	Description											
0x0	100 µs debounce											
0x1	1 ms debounce											
0x2	10 ms debounce											
0x3	100 ms debounce											
[3]	GPIO0_PUPD	<p>GPIO pull-up/pull-down enable</p> <table> <thead> <tr> <th>Value</th> <th>Description</th> </tr> </thead> <tbody> <tr> <td>0x0</td> <td>GPI: pull-down disabled, GPO: pull-up to AVDD disabled</td> </tr> </tbody> </table>	Value	Description	0x0	GPI: pull-down disabled, GPO: pull-up to AVDD disabled						
Value	Description											
0x0	GPI: pull-down disabled, GPO: pull-up to AVDD disabled											

**High-Performance, 10 A,
Dual-Phase DC-DC Converter**

Bit	Symbol	Description
		0x1 GPI: pull-down enabled, GPO: pull-up to AVDD enabled
[2]	GPIO0_POL	GPIO polarity Value Description 0x0 GPIO is active-high 0x1 GPIO is active-low
[1:0]	GPIO0_TRIG	GPI trigger type Value Description 0x0 Dual-edge triggered 0x1 Pos-edge triggered 0x2 Neg-edge triggered 0x3 Reserved (No trigger)

Table 35: SYS_GPIO1_0 (0x0012)

Bit	Symbol	Description
[4:1]	GPIO1_MODE	GPIO function mode select. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1 Value Description 0x0 GPIO disable 0x1 EN1 input 0x2 Reserved 0x3 Reserved 0x4 DVC1 input 0x5 Reserved 0x6 Reserved 0x7 RELOAD input 0x8 PG1 output 0x9 Reserved 0xA Reserved 0xB Reserved 0xC nIRQ output 0xD Reserved 0xE Low output 0xF High output
[0]	GPIO1_OBUF	GPIO output buffer select. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1 Value Description 0x0 open-drain output 0x1 push-pull output

**High-Performance, 10 A,
Dual-Phase DC-DC Converter**
Table 36: SYS_GPIO1_1 (0x0013)

Bit	Symbol	Description										
[7]	GPIO1_DEB_FALL	GPI debounce falling edge. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1										
[6]	GPIO1_DEB_RISE	GPI debounce rising edge. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1										
[5:4]	GPIO1_DEB	GPI debounce time. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1 <table> <thead> <tr> <th>Value</th><th>Description</th></tr> </thead> <tbody> <tr> <td>0x0</td><td>100 μs debounce</td></tr> <tr> <td>0x1</td><td>1 ms debounce</td></tr> <tr> <td>0x2</td><td>10 ms debounce</td></tr> <tr> <td>0x3</td><td>100 ms debounce</td></tr> </tbody> </table>	Value	Description	0x0	100 μ s debounce	0x1	1 ms debounce	0x2	10 ms debounce	0x3	100 ms debounce
Value	Description											
0x0	100 μ s debounce											
0x1	1 ms debounce											
0x2	10 ms debounce											
0x3	100 ms debounce											
[3]	GPIO1_PUPD	GPIO pull-up/pull-down enable. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1 <table> <thead> <tr> <th>Value</th><th>Description</th></tr> </thead> <tbody> <tr> <td>0x0</td><td>GPI: pull-down disabled, GPO: pull-up to AVDD disabled</td></tr> <tr> <td>0x1</td><td>GPI: pull-down enabled, GPO: pull-up to AVDD enabled</td></tr> </tbody> </table>	Value	Description	0x0	GPI: pull-down disabled, GPO: pull-up to AVDD disabled	0x1	GPI: pull-down enabled, GPO: pull-up to AVDD enabled				
Value	Description											
0x0	GPI: pull-down disabled, GPO: pull-up to AVDD disabled											
0x1	GPI: pull-down enabled, GPO: pull-up to AVDD enabled											
[2]	GPIO1_POL	GPIO polarity. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1 <table> <thead> <tr> <th>Value</th><th>Description</th></tr> </thead> <tbody> <tr> <td>0x0</td><td>GPIO is active-high</td></tr> <tr> <td>0x1</td><td>GPIO is active-low</td></tr> </tbody> </table>	Value	Description	0x0	GPIO is active-high	0x1	GPIO is active-low				
Value	Description											
0x0	GPIO is active-high											
0x1	GPIO is active-low											
[1:0]	GPIO1_TRIG	GPI trigger type. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1 <table> <thead> <tr> <th>Value</th><th>Description</th></tr> </thead> <tbody> <tr> <td>0x0</td><td>Dual-edge triggered</td></tr> <tr> <td>0x1</td><td>Pos-edge triggered</td></tr> <tr> <td>0x2</td><td>Neg-edge triggered</td></tr> <tr> <td>0x3</td><td>Reserved (No trigger)</td></tr> </tbody> </table>	Value	Description	0x0	Dual-edge triggered	0x1	Pos-edge triggered	0x2	Neg-edge triggered	0x3	Reserved (No trigger)
Value	Description											
0x0	Dual-edge triggered											
0x1	Pos-edge triggered											
0x2	Neg-edge triggered											
0x3	Reserved (No trigger)											

Table 37: SYS_GPIO2_0 (0x0014)

Bit	Symbol	Description										
[4:1]	GPIO2_MODE	GPIO function mode select. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1 <table> <thead> <tr> <th>Value</th><th>Description</th></tr> </thead> <tbody> <tr> <td>0x0</td><td>GPIO disable</td></tr> <tr> <td>0x1</td><td>EN1 input</td></tr> <tr> <td>0x2</td><td>Reserved</td></tr> <tr> <td>0x3</td><td>Reserved</td></tr> </tbody> </table>	Value	Description	0x0	GPIO disable	0x1	EN1 input	0x2	Reserved	0x3	Reserved
Value	Description											
0x0	GPIO disable											
0x1	EN1 input											
0x2	Reserved											
0x3	Reserved											

**High-Performance, 10 A,
Dual-Phase DC-DC Converter**

Bit	Symbol	Description						
		0x4 DVC1 input 0x5 Reserved 0x6 Reserved 0x7 RELOAD input 0x8 PG1 output 0x9 Reserved 0xA Reserved 0xB Reserved 0xC nIRQ output 0xD Reserved 0xE Low output 0xF High output						
[0]	GPIO2_OBUF	GPIO output buffer select. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1 <table> <thead> <tr> <th>Value</th><th>Description</th></tr> </thead> <tbody> <tr> <td>0x0</td><td>open-drain output</td></tr> <tr> <td>0x1</td><td>push-pull output</td></tr> </tbody> </table>	Value	Description	0x0	open-drain output	0x1	push-pull output
Value	Description							
0x0	open-drain output							
0x1	push-pull output							

Table 38: SYS_GPIO2_1 (0x0015)

Bit	Symbol	Description										
[7]	GPIO2_DEB_FALL	GPI debounce falling edge. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1										
[6]	GPIO2_DEB_RISE	GPI debounce rising edge. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1										
[5:4]	GPIO2_DEB	GPI debounce time. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1 <table> <thead> <tr> <th>Value</th><th>Description</th></tr> </thead> <tbody> <tr> <td>0x0</td><td>100 μs debounce</td></tr> <tr> <td>0x1</td><td>1 ms debounce</td></tr> <tr> <td>0x2</td><td>10 ms debounce</td></tr> <tr> <td>0x3</td><td>100 ms debounce</td></tr> </tbody> </table>	Value	Description	0x0	100 μ s debounce	0x1	1 ms debounce	0x2	10 ms debounce	0x3	100 ms debounce
Value	Description											
0x0	100 μ s debounce											
0x1	1 ms debounce											
0x2	10 ms debounce											
0x3	100 ms debounce											
[3]	GPIO2_PUPD	GPIO pull-up/pull-down enable. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1 <table> <thead> <tr> <th>Value</th><th>Description</th></tr> </thead> <tbody> <tr> <td>0x0</td><td>GPI: pull-down disabled, GPO: pull-up to AVDD disabled</td></tr> <tr> <td>0x1</td><td>GPI: pull-down enabled, GPO: pull-up to AVDD enabled</td></tr> </tbody> </table>	Value	Description	0x0	GPI: pull-down disabled, GPO: pull-up to AVDD disabled	0x1	GPI: pull-down enabled, GPO: pull-up to AVDD enabled				
Value	Description											
0x0	GPI: pull-down disabled, GPO: pull-up to AVDD disabled											
0x1	GPI: pull-down enabled, GPO: pull-up to AVDD enabled											
[2]	GPIO2_POL	GPIO polarity. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1 <table> <thead> <tr> <th>Value</th><th>Description</th></tr> </thead> </table>	Value	Description								
Value	Description											

High-Performance, 10 A, Dual-Phase DC-DC Converter

Bit	Symbol	Description
		0x0 GPIO is active-high 0x1 GPIO is active-low
[1:0]	GPIO2_TRIG	GPI trigger type. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1 Value Description 0x0 Dual-edge triggered 0x1 Pos-edge triggered 0x2 Neg-edge triggered 0x3 Reserved (No trigger)

High-Performance, 10 A, Dual-Phase DC-DC Converter

5.1.2 Buck1

Table 39: BUCK_BUCK1_0 (0x0020)

Bit	Symbol	Description																		
[6:4]	CH1_SR_DVC_DWN	<p>Voltage slew-rate for DVC ramp-down</p> <table> <thead> <tr> <th>Value</th><th>Description</th></tr> </thead> <tbody> <tr> <td>0x0</td><td>10 mV/8 μs</td></tr> <tr> <td>0x1</td><td>10 mV/4 μs</td></tr> <tr> <td>0x2</td><td>10 mV/2 μs</td></tr> <tr> <td>0x3</td><td>10 mV/μs</td></tr> <tr> <td>0x4</td><td>20 mV/μs</td></tr> <tr> <td>0x5</td><td>Reserved</td></tr> <tr> <td>0x6</td><td>Reserved</td></tr> <tr> <td>0x7</td><td>Reserved</td></tr> </tbody> </table>	Value	Description	0x0	10 mV/8 μ s	0x1	10 mV/4 μ s	0x2	10 mV/2 μ s	0x3	10 mV/ μ s	0x4	20 mV/μs	0x5	Reserved	0x6	Reserved	0x7	Reserved
Value	Description																			
0x0	10 mV/8 μ s																			
0x1	10 mV/4 μ s																			
0x2	10 mV/2 μ s																			
0x3	10 mV/ μ s																			
0x4	20 mV/μs																			
0x5	Reserved																			
0x6	Reserved																			
0x7	Reserved																			
[3:1]	CH1_SR_DVC_UP	<p>Voltage slew-rate for DVC ramp-up</p> <table> <thead> <tr> <th>Value</th><th>Description</th></tr> </thead> <tbody> <tr> <td>0x0</td><td>10 mV/8 μs</td></tr> <tr> <td>0x1</td><td>10 mV/4 μs</td></tr> <tr> <td>0x2</td><td>10 mV/2 μs</td></tr> <tr> <td>0x3</td><td>10 mV/μs</td></tr> <tr> <td>0x4</td><td>20 mV/μs</td></tr> <tr> <td>0x5</td><td>40 mV/μs</td></tr> <tr> <td>0x6</td><td>Reserved</td></tr> <tr> <td>0x7</td><td>Reserved</td></tr> </tbody> </table>	Value	Description	0x0	10 mV/8 μ s	0x1	10 mV/4 μ s	0x2	10 mV/2 μ s	0x3	10 mV/ μ s	0x4	20 mV/μs	0x5	40 mV/ μ s	0x6	Reserved	0x7	Reserved
Value	Description																			
0x0	10 mV/8 μ s																			
0x1	10 mV/4 μ s																			
0x2	10 mV/2 μ s																			
0x3	10 mV/ μ s																			
0x4	20 mV/μs																			
0x5	40 mV/ μ s																			
0x6	Reserved																			
0x7	Reserved																			
[0]	CH1_EN	Channel enable. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1																		

Table 40: BUCK_BUCK1_1 (0x0021)

Bit	Symbol	Description																		
[6:4]	CH1_SR_SHDN	<p>Voltage slew-rate during shut-down</p> <table> <thead> <tr> <th>Value</th><th>Description</th></tr> </thead> <tbody> <tr> <td>0x0</td><td>10 mV/8 μs</td></tr> <tr> <td>0x1</td><td>10 mV/4 μs</td></tr> <tr> <td>0x2</td><td>10 mV/2 μs</td></tr> <tr> <td>0x3</td><td>10 mV/μs</td></tr> <tr> <td>0x4</td><td>20 mV/μs</td></tr> <tr> <td>0x5</td><td>Reserved</td></tr> <tr> <td>0x6</td><td>Reserved</td></tr> <tr> <td>0x7</td><td>Immediate power-down</td></tr> </tbody> </table>	Value	Description	0x0	10 mV/8 μ s	0x1	10 mV/4 μ s	0x2	10 mV/2 μ s	0x3	10 mV/ μ s	0x4	20 mV/μs	0x5	Reserved	0x6	Reserved	0x7	Immediate power-down
Value	Description																			
0x0	10 mV/8 μ s																			
0x1	10 mV/4 μ s																			
0x2	10 mV/2 μ s																			
0x3	10 mV/ μ s																			
0x4	20 mV/μs																			
0x5	Reserved																			
0x6	Reserved																			
0x7	Immediate power-down																			
[3:1]	CH1_SR_STARTUP	Voltage slew-rate during startup																		

**High-Performance, 10 A,
Dual-Phase DC-DC Converter**

Bit	Symbol	Description	
		Value	Description
		0x0	10 mV/8 μ s
		0x1	10 mV/4 μ s
		0x2	10 mV/2 μ s
		0x3	10 mV/ μ s
		0x4	20 mV/μs
		0x5	40 mV/ μ s
		0x6	Reserved
		0x7	Reserved
[0]	CH1_PD_DIS	Pull-down while buck is disabled. 0: enable, 1: disable	

Table 41: BUCK_BUCK1_2 (0x0022)

Bit	Symbol	Description	
[3:0]	CH1_ILIM	Select OCP threshold (A)	
		Value	Description
		0x0	Reserved
		0x1	3.5
		0x2	4.0
		0x3	4.5
		0x4	5.0
		0x5	5.5
		0x6	6.0
		0x7	6.5
		0x8	7.0
		0x9	7.5
		0xA	8.0
		0xB	8.5
		0xC	9.0
		0xD	9.5
		0xE	10.0
		0xF	Disable

Table 42: BUCK_BUCK1_3 (0x0023)

Bit	Symbol	Description	
[7:0]	CH1_VMAX	VOUT max setting (V): From 0.30 V (0x1E) to 1.90 V (0xBE) in 10 mV steps. This is a read-only register.	
		Value	Description
		0x1E	0.3

**High-Performance, 10 A,
Dual-Phase DC-DC Converter**

Bit	Symbol	Description
		0x1F 0.31
		0x20 0.32
		Continuing through...
		0x99 1.53
		To...
		0xBD 1.89
		0xBE 1.9

Table 43: BUCK_BUCK1_4 (0x0024)

Bit	Symbol	Description										
[4]	CH1_VSEL	Output voltage and operation selection: 0: A, 1: B. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1										
[3:2]	CH1_B_MODE	Operation mode selection. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1 <table border="0"> <tr> <th>Value</th> <th>Description</th> </tr> <tr> <td>0x0</td> <td>Force PFM operation</td> </tr> <tr> <td>0x1</td> <td>Force PWM operation (full phase)</td> </tr> <tr> <td>0x2</td> <td>Force PWM operation (with phase shedding)</td> </tr> <tr> <td>0x3</td> <td>Auto mode</td> </tr> </table>	Value	Description	0x0	Force PFM operation	0x1	Force PWM operation (full phase)	0x2	Force PWM operation (with phase shedding)	0x3	Auto mode
Value	Description											
0x0	Force PFM operation											
0x1	Force PWM operation (full phase)											
0x2	Force PWM operation (with phase shedding)											
0x3	Auto mode											
[1:0]	CH1_A_MODE	Operation mode selection. Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1 <table border="0"> <tr> <th>Value</th> <th>Description</th> </tr> <tr> <td>0x0</td> <td>Force PFM operation</td> </tr> <tr> <td>0x1</td> <td>Force PWM operation (full phase)</td> </tr> <tr> <td>0x2</td> <td>Force PWM operation (with phase shedding)</td> </tr> <tr> <td>0x3</td> <td>Auto mode</td> </tr> </table>	Value	Description	0x0	Force PFM operation	0x1	Force PWM operation (full phase)	0x2	Force PWM operation (with phase shedding)	0x3	Auto mode
Value	Description											
0x0	Force PFM operation											
0x1	Force PWM operation (full phase)											
0x2	Force PWM operation (with phase shedding)											
0x3	Auto mode											

Table 44: BUCK_BUCK1_5 (0x0025)

Bit	Symbol	Description								
[7:0]	CH1_A_VOUT	Output voltage setting A: Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1 From 0.30 V (0x1E) to 1.90 V (0xBE) in steps of 10 mV (default 1.0 V) Write-protected when value is written below 0.30 V or above 1.90 V <table border="0"> <tr> <th>Value</th> <th>Description</th> </tr> <tr> <td>0x1E</td> <td>0.3</td> </tr> <tr> <td>0x1F</td> <td>0.31</td> </tr> <tr> <td>0x20</td> <td>0.32</td> </tr> </table>	Value	Description	0x1E	0.3	0x1F	0.31	0x20	0.32
Value	Description									
0x1E	0.3									
0x1F	0.31									
0x20	0.32									

**High-Performance, 10 A,
Dual-Phase DC-DC Converter**

Bit	Symbol	Description
		<p>Continuing through...</p> <p>0x64 1</p> <p>To...</p> <p>0xBC 1.88</p> <p>0xBD 1.89</p> <p>0xBE 1.9</p>

Table 45: BUCK_BUCK1_6 (0x0026)

Bit	Symbol	Description																				
[7:0]	CH1_B_VOUT	<p>Output voltage setting B: Initial value is determined by CONF pin setting at the start-up in CONF_EN = 1 From 0.30 V (0x1E) to 1.90 V (0xBE) in steps of 10 mV (default 1.0 V)</p> <p>Write-protected when value is written below 0.30 V or above 1.90 V</p> <table> <thead> <tr> <th>Value</th> <th>Description</th> </tr> </thead> <tbody> <tr> <td>0x1E</td> <td>0.3</td> </tr> <tr> <td>0x1F</td> <td>0.31</td> </tr> <tr> <td>0x20</td> <td>0.32</td> </tr> <tr> <td>Continuing through...</td> <td></td> </tr> <tr> <td>0x64</td> <td>1</td> </tr> <tr> <td>To...</td> <td></td> </tr> <tr> <td>0xBC</td> <td>1.88</td> </tr> <tr> <td>0xBD</td> <td>1.89</td> </tr> <tr> <td>0xBE</td> <td>1.9</td> </tr> </tbody> </table>	Value	Description	0x1E	0.3	0x1F	0.31	0x20	0.32	Continuing through...		0x64	1	To...		0xBC	1.88	0xBD	1.89	0xBE	1.9
Value	Description																					
0x1E	0.3																					
0x1F	0.31																					
0x20	0.32																					
Continuing through...																						
0x64	1																					
To...																						
0xBC	1.88																					
0xBD	1.89																					
0xBE	1.9																					

**High-Performance, 10 A,
Dual-Phase DC-DC Converter****5.1.3 Serialization****Table 46: OTP_DEVICE_ID (0x0048)**

Bit	Symbol	Description
[7:0]	DEV_ID	Device ID

Table 47: OTP_VARIANT_ID (0x0049)

Bit	Symbol	Description
[7:4]	MRC	Mask Revision Code
[3:0]	VRC	Chip Variant Code

Table 48: OTP_CUSTOMER_ID (0x004A)

Bit	Symbol	Description
[7:0]	CUST_ID	Customer ID

Table 49: OTP_CONFIG_ID (0x004B)

Bit	Symbol	Description
[7:0]	CONFIG_REV	OTP Variant

High-Performance, 10 A, Dual-Phase DC-DC Converter

6 Package Information

6.1 Package Outlines

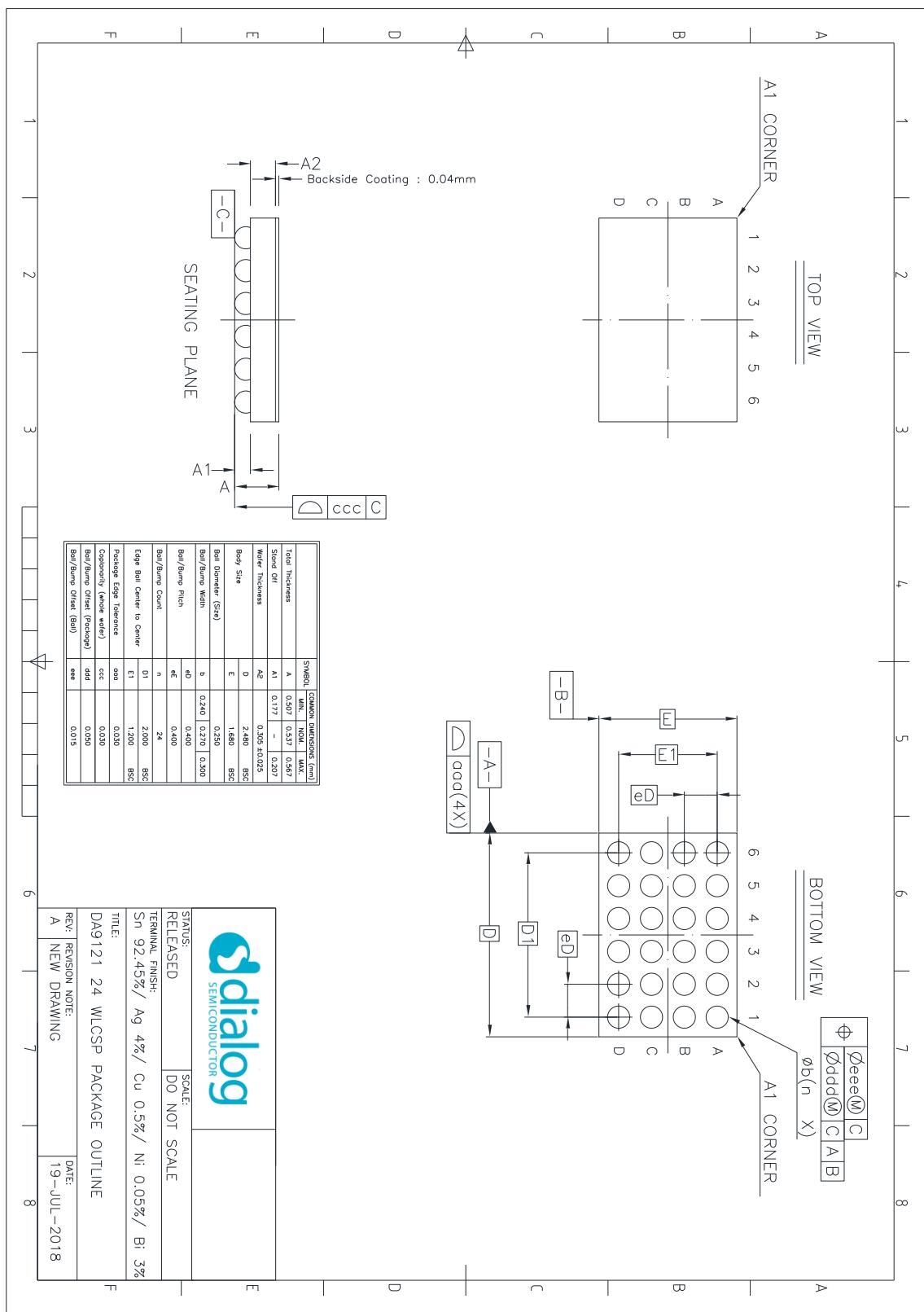


Figure 21: WLCSP Package Outline Drawing

High-Performance, 10 A, Dual-Phase DC-DC Converter

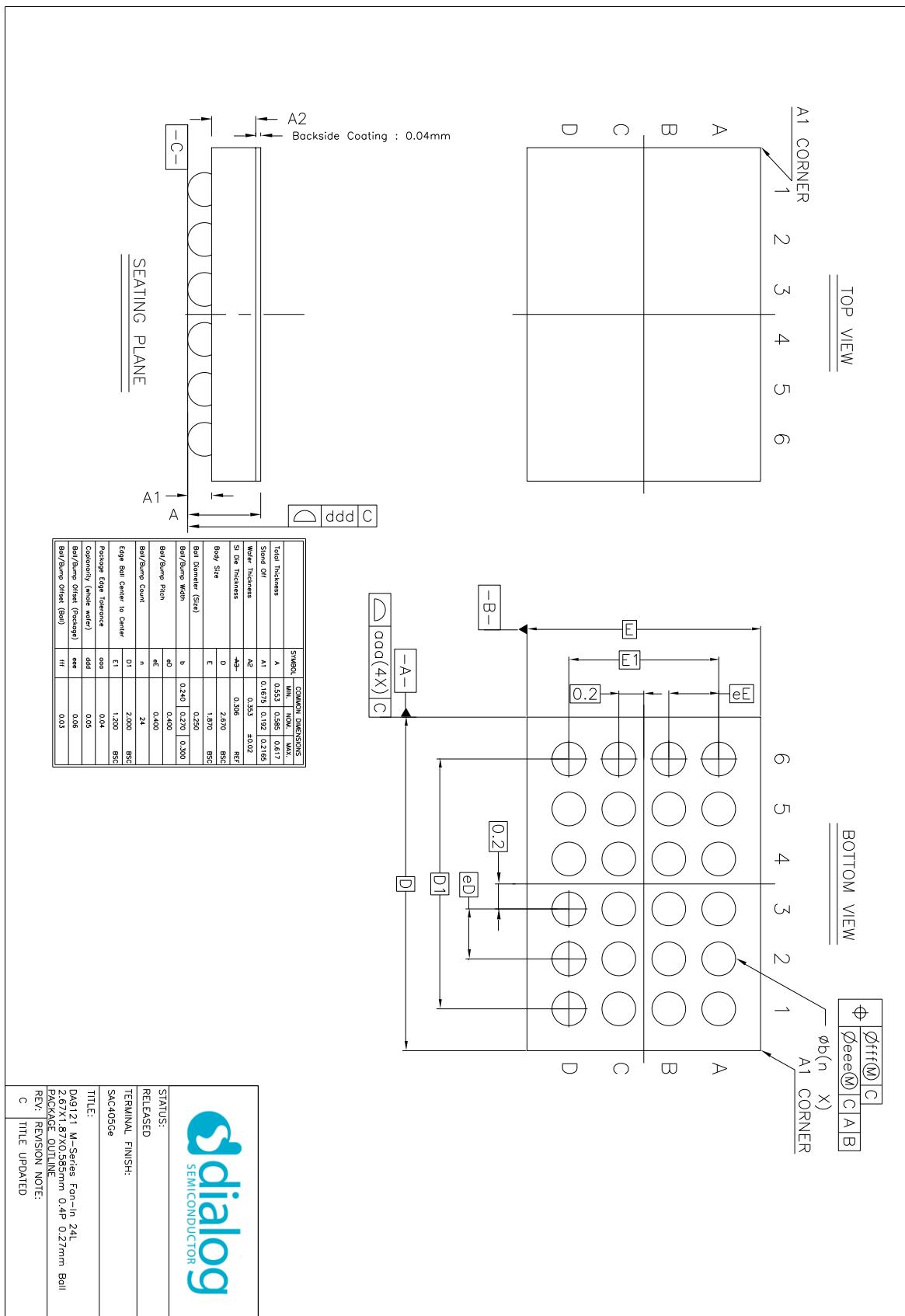


Figure 22: WLP Package Outline Drawing

High-Performance, 10 A, Dual-Phase DC-DC Converter

6.2 Moisture Sensitivity Level

The moisture sensitivity level (MSL) is an indicator for the maximum allowable time period (floor lifetime) in which a moisture sensitive plastic device, once removed from the dry bag, can be exposed to an environment with a specified maximum temperature and a maximum relative humidity before the solder reflow process. The MSL classification is defined in [Table 50](#).

For detailed information on MSL levels refer to the IPC/JEDEC standard J-STD-020, which can be downloaded from <http://www.jedec.org>.

The DA9121 package is qualified for MSL1.

Table 50: MSL Classification

MSL Level	Floor Lifetime	Conditions
MSL 1	Unlimited	$\leq 30^{\circ}\text{C} / 85\% \text{ RH}$

6.3 Package Handling

Manual handling of WLCSP packages should be reduced to the absolute minimum. In cases where it is still necessary, a vacuum pick-up tool should be used. In extreme cases plastic tweezers could be used, but metal tweezers are not acceptable, since contact may easily damage the silicon chip.

Removal of a WLP or WLCSP package will cause damage to the solder balls. Therefore a removed sample cannot be reused.

WLCSP packages are sensitive to visible and infrared light. For light sensitive applications, the WLP package should be used.

6.4 Soldering Information

Refer to the IPC/JEDEC standard J-STD-020 for relevant soldering information. This document can be downloaded from <http://www.jedec.org>.

High-Performance, 10 A, Dual-Phase DC-DC Converter

7 Ordering Information

The ordering number consists of the part number followed by a suffix indicating the packing method. For details and availability, please consult Dialog Semiconductor's [customer support portal](#) or your local sales representative.

Table 51: Ordering Information

Part Number	Package	Size (mm)	Shipment Form	Pack Quantity
DA9121-xxV72	24 WLCSP	2.5 x 1.7	T&R	4500
DA9121-xxV76	24 WLCSP	2.5 x 1.7	Waffle Tray	140
DA9121-B0V72 Standard OTP Variant $V_{OUT1} = 1.0$ V	24 WLCSP	2.5 x 1.7	T&R	4500
DA9121-B0V76 Standard OTP Variant $V_{OUT1} = 1.0$ V	24 WLCSP	2.5 x 1.7	Waffle Tray	140
DA9121-xxOZ2	24 WLP	2.7 x 1.9	T&R	TBD
DA9121-xxOZ6	24 WLP	2.7 x 1.9	Waffle Tray	TBD
DA9121-B0OZ2 Standard OTP Variant $V_{OUT1} = 1.0$ V	24 WLP	2.7 x 1.9	T&R	TBD

8 Application Information

The following recommended components are examples selected from requirements of a typical application.

8.1 Capacitor Selection

Ceramic capacitors are used as bypass capacitors at all VDD and output rails. When selecting a capacitor, especially for types with high capacitance at smallest physical dimension, the DC bias characteristic has to be taken into account.

Table 52: Recommended Capacitor Types

Application	Value	Size	Temp. Char.	Tol. (%)	V-Rate	Type
V _{OUT} output bypass	10 μ F	0402	X5R ± 15 %	± 20	6.3 V	Murata GRM155R60J106ME15
PVDDx bypass	10 μ F	0603	X5R ± 15 %	± 20	25 V	Murata GRM188R61E106MA73
AVDD bypass	1 μ F	0402	X5R ± 15 %	± 10	10 V	Murata GRM155R61A105KE15

High-Performance, 10 A, Dual-Phase DC-DC Converter

8.2 Inductor Selection

Inductors should be selected based on the following parameters:

- Rated maximum current

Usually a coil provides two current limits: ISAT specifies the maximum current at which the inductance drops by 30 % of the nominal value, and IMAX is defined by the maximum power dissipation and is applied to the effective current.

- DC resistance

Critical for the converter efficiency and should therefore be minimized.

Table 53: Recommended Inductor Types

Value (μ H)	Size (mm)	IMAX (DC) (A)	ISAT (A)	Tol. (%)	DC Resistance (m Ω)	Type
0.1	2.0 x 1.6 x 1.0	6.5	9.0	± 20	11.5	Cyntec HTEN20161T-R10MDR
0.1	1.6 x 0.8 x 1.0	5.2	6.5	± 20	17	Taiyo Yuden MEKK1608TR10M
0.1	1.6 x 0.8 x 0.8	4.1	9.4	± 20	19	Taiyo Yuden MCHK1608TR10MJN
0.11	2.0 x 1.25 x 0.8	5.8	6.9	± 20	9.1	Taiyo Yuden MCHK2012TR11MKG
0.1	2.5 x 2.0 x 1.2	12	13	± 20	4	TDK TFM252012ALMAR10MT
0.1	1.6 x 0.8 x 0.95	3.8	4.3	± 20	15	Tokyo Coil Engineering TFP160810M-R10N
0.11	2.0 x 1.6 x 0.6	3.0	6.0	± 20	24	Wurth Elektronik WE-PMMI 744 799 771 11

High-Performance, 10 A, Dual-Phase DC-DC Converter

9 Revision History

Revision	Date	Description
2.4	15-Feb-2022	Modification: Rebranded to Renesas
2.3	18-Sep-2020	Modification: Section 4.2.3.4: Added new section Section 8.2: Updated Table 53
2.2	15-May-2020	Modification: Section 3.3.1: Added typical value for WLP package thermal resistance Section 3.3.2: Added Figure 6: 24WLP Power Derating Curve Section 6.1: Updated POD for WLP
2.1	29-Nov-2019	Modifications: Updated Key Features with WLP package information Section 3.3.1: Added package thermal ratings for WLP Section 6.3: Updated package handling for WLP Section 6.1: Added Figure 22 Section 7: Updated Table 51: Ordering Information with WLP ordering information
2.0	18-Jul-2019	Modifications: Section 3.5: Updated Buck R_{PD} condition Section 3.9: Added typical performance graphs Section 7: Updated Table 51: Ordering Information
1.1	07-Mar-2019	Modifications: Section 3.5: Updated Buck t_{BUCK_EN} parameter condition and value, R_{PD} parameter description Section 3.7 Updated R_{PD} and R_{PU} parameter values Section 8.2: Updated Table 53: Recommended Inductor Types Removed watermark
1.0	02-Oct-2018	Modifications: Section 3.5: Updated Buck $V_{OUT_TR_LINE}$, $V_{OUT_TR_LD_2PH}$, and $I_{Q_PFM_2PH}$ parameter descriptions Section 5.1: Updated Register map Section 5.1.2: Updated BUCK_BUCK1_4 register bit descriptions
0.2	28-Sep-2018	Modifications: Section 3.5: Updated Buck R_{ON_PMOS} and R_{ON_NMOS} parameter values Section 3.6: Updated V_{THR_POR} parameter and added $V_{THR_POR_HYS}$ parameter
0.1	19-Jul-2018	Initial version.

High-Performance, 10 A, Dual-Phase DC-DC Converter

Status Definitions

Revision	Datasheet Status	Product Status	Definition
1.<n>	Target	Development	This datasheet contains the design specifications for product development. Specifications may be changed in any manner without notice.
2.<n>	Preliminary	Qualification	This datasheet contains the specifications and preliminary characterization data for products in pre-production. Specifications may be changed at any time without notice in order to improve the design.
3.<n>	Final	Production	This datasheet contains the final specifications for products in volume production. The specifications may be changed at any time in order to improve the design, manufacturing and supply. Major specification changes are communicated via Customer Product Notifications. Datasheet changes are communicated via www.dialog-semiconductor.com .
4.<n>	Obsolete	Archived	This datasheet contains the specifications for discontinued products. The information is provided for reference only.

RoHS Compliance

Dialog Semiconductor's suppliers certify that its products are in compliance with the requirements of Directive 2011/65/EU of the European Parliament on the restriction of the use of certain hazardous substances in electrical and electronic equipment. RoHS certificates from our suppliers are available on request.

High-Performance, 10 A, Dual-Phase DC-DC Converter

Important Notice and Disclaimer

RENESAS ELECTRONICS CORPORATION AND ITS SUBSIDIARIES ("RENESAS") PROVIDES TECHNICAL SPECIFICATIONS AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS OR IMPLIED, INCLUDING, WITHOUT LIMITATION, ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for developers skilled in the art designing with Renesas products. You are solely responsible for (1) selecting the appropriate products for your application, (2) designing, validating, and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. Renesas grants you permission to use these resources only for development of an application that uses Renesas products. Other reproduction or use of these resources is strictly prohibited. No license is granted to any other Renesas intellectual property or to any third party intellectual property. Renesas disclaims responsibility for, and you will fully indemnify Renesas and its representatives against, any claims, damages, costs, losses, or liabilities arising out of your use of these resources. Renesas' products are provided only subject to Renesas' Terms and Conditions of Sale or other applicable terms agreed to in writing. No use of any Renesas resources expands or otherwise alters any applicable warranties or warranty disclaimers for these products.

© 2022 Renesas Electronics Corporation. All rights reserved.

(Rev.1.0 Mar 2020)

Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu

Koto-ku, Tokyo 135-0061, Japan

www.renesas.com

Contact Information

For further information on a product, technology, the most up-to-date version of a document, or your nearest sales office, please visit:

<https://www.renesas.com/contact/>

Trademarks

Renesas and the Renesas logo are trademarks of Renesas Electronics Corporation. All trademarks and registered trademarks are the property of their respective owners.

IMPORTANT NOTICE AND DISCLAIMER

RENESAS ELECTRONICS CORPORATION AND ITS SUBSIDIARIES ("RENESAS") PROVIDES TECHNICAL SPECIFICATIONS AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS OR IMPLIED, INCLUDING, WITHOUT LIMITATION, ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, OR NON-INFRINGEMENT OF THIRD-PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for developers who are designing with Renesas products. You are solely responsible for (1) selecting the appropriate products for your application, (2) designing, validating, and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. Renesas grants you permission to use these resources only to develop an application that uses Renesas products. Other reproduction or use of these resources is strictly prohibited. No license is granted to any other Renesas intellectual property or to any third-party intellectual property. Renesas disclaims responsibility for, and you will fully indemnify Renesas and its representatives against, any claims, damages, costs, losses, or liabilities arising from your use of these resources. Renesas' products are provided only subject to Renesas' Terms and Conditions of Sale or other applicable terms agreed to in writing. No use of any Renesas resources expands or otherwise alters any applicable warranties or warranty disclaimers for these products.

(Disclaimer Rev.1.01)

Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu,
Koto-ku, Tokyo 135-0061, Japan
www.renesas.com

Trademarks

Renesas and the Renesas logo are trademarks of Renesas Electronics Corporation. All trademarks and registered trademarks are the property of their respective owners.

Contact Information

For further information on a product, technology, the most up-to-date version of a document, or your nearest sales office, please visit www.renesas.com/contact-us/.